

16M-BIT [x 1 / x 2] CMOS SERIAL FLASH 32M-BIT [x 1 / x 2] CMOS SERIAL FLASH 64M-BIT [x 1 / x 2] CMOS SERIAL FLASH

FEATURES

GENERAL

- Serial Peripheral Interface compatible -- Mode 0 and Mode 3
- 16M:16,777,216 x 1 bit structure or 8,388,608 x 2 bits (two I/O read mode) structure 32M:33,554,432 x 1 bit structure or 16,772,216 x 2 bits (two I/O read mode) structure 64M:67,108,864 x 1 bit structure or 33,554,432 x 2 bits (two I/O read mode) structure
- 512 Equal Sectors with 4K byte each (16Mb) 1024 Equal Sectors with 4K byte each (32Mb) 2048 Equal Sectors with 4K byte each (64Mb)
 Any Sector can be erased individually
- 32 Equal Blocks with 64K byte each (16Mb)
 64 Equal Blocks with 64K byte each (32Mb)
 128 Equal Blocks with 64K byte each (64Mb)
 Any Block can be erased individually
- Single Power Supply Operation
- 2.7 to 3.6 volt for read, erase, and program operations
- Latch-up protected to 100mA from -1V to Vcc +1V
- Low Vcc write inhibit is from 1.5V to 2.5V

PERFORMANCE

- High Performance
 - Fast access time: 86MHz serial clock (15pF + 1TTL Load) and 66MHz serial clock (30pF + 1TTL Load)
 - * Serial clock of two I/O read mode : 50MHz (15pF + TTL Load), which is equivalent to 100MHz
 - Fast program time: 1.4ms(typ.) and 5ms(max.)/page (256-byte per page)
 - Byte program time: 9us (typical)
 - Continuously program mode (automatically increase address under word program mode)
 - Fast erase time: 60ms(typ.) /sector (4K-byte per sector); 0.7s(typ.) /block (64K-byte per block); 14s(typ.) /chip for
 - 16Mb, 25s(typ.) for 32Mb, and 50s(typ.) for 64Mb
- Low Power Consumption
 - Low active read current: 25mA(max.) at 86MHz, 20mA(max.) at 66MHz and 10mA(max.) at 33MHz
 - Low active programming current: 20mA (max.)
 - Low active erase current: 20mA (max.)
 - Low standby current: 20uA (max.)
 - Deep power-down mode 1uA (typical)
- Typical 100,000 erase/program cycles

SOFTWARE FEATURES

- Input Data Format
 - 1-byte Command code
- Advanced Security Features
 - Block lock protection

The BP0-BP3 status bit defines the size of the area to be software protection against program and erase instructions

- Additional 512-bit secured OTP for unique identifier
- Auto Erase and Auto Program Algorithm
 - Automatically erases and verifies data at selected sector

- Automatically programs and verifies data at selected page by an internal algorithm that automatically times the program pulse widths (Any page to be programed should have page in the erased state first)



- Status Register Feature
- Electronic Identification
 - JEDEC 1-byte manufacturer ID and 2-byte device ID
 - RES command for 1-byte Device ID
 - Both REMS and REMS2 commands for 1-byte manufacturer ID and 1-byte device ID

HARDWAREFEATURES

- SCLK Input
 - Serial clock input
- SI Input
- Serial Data Input
- SO Output
 - Serial Data Output
- WP#/ACC pin
 - Hardware write protection and program/erase acceleration
- HOLD# pin
 - pause the chip without diselecting the chip
- PACKAGE
 - 16-pin SOP (300mil)
 - 8-land WSON (8x6mm or6x5mm)
 - 8-pin SOP (200mil, 150mil)
 - 8-pin PDIP (300mil)
 - All Pb-free devices are RoHS Compliant

ALTERNATIVE

• Security Serial Flash (MX25L1615D/MX25L3215D/MX25L6415D) may provides additional protection features for option. The datasheet is provided under NDA.

GENERAL DESCRIPTION

The MX25L1605D are 16,777,216 bit serial Flash memory, which is configured as 2,097,152 x 8 internally. When it is in two I/O read mode, the structure becomes 8,388,608 bits x 2. The MX25L3205D are 33,554,432 bit serial Flash memory, which is configured as 4,194,304 x 8 internally. When it is in two I/O read mode, the structure becomes 16,772,216 bits x 2. The MX25L6405D are 67,108,864 bit serial Flash memory, which is configured as 8,388,608 x 8 internally. When it is in two I/O read mode, the structure becomes 33,554,432 bits x 2. (please refer to the "Two I/O Read mode" section). The MX25L1605D/3205D/6405D feature a serial peripheral interface and software protocol allowing operation on a simple 3-wire bus. The three bus signals are a clock input (SCLK), a serial data input (SI), and a serial data output (SO). Serial access to the device is enabled by CS# input.

When it is in two I/O read mode, the SI pin and SO pin become SIO0 pin and SIO1 pin for address/dummy bits input and data output.

The MX25L1605D/3205D/6405D provides sequential read operation on whole chip.

After program/erase command is issued, auto program/erase algorithms which program/erase and verify the specified page or sector/block locations will be executed. Program command is executed on byte basis, or page (256 bytes) basis, or word basis for Continuously program mode, and erase command is executes on sector (4K-byte), or block (64K-byte), or whole chip basis.



To provide user with ease of interface, a status register is included to indicate the status of the chip. The status read command can be issued to detect completion status of a program or erase operation via WIP bit.

Advanced security features enhance the protection and security functions, please see security features section for more details.

When the device is not in operation and CS# is high, it is put in standby mode and draws less than 20uA DC current.

The MX25L1605D/3205D/6405D utilizes MXIC's proprietary memory cell, which reliably stores memory contents even after typical 100,000 program and erase cycles.

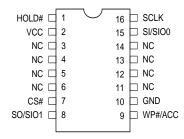
| Additional | Protection a | and Security | Read Performance | | lde | entifier | |
|----------------------------|--|------------------------|-------------------------|------------------------------------|------------------------------------|------------------------------------|------------------------------|
| Featu- res Part Name | Flexible Block protection (BP0-BP3) | 512-bit secured OTP | * 2 I/O Read (50MHz) | Device ID (command : AB hex) | Device ID (command : 90 hex) | Device ID (command : EF hex) | RDID (command: 9F hex) |
| MX25L1605D | V | V | V | 14 (hex) | C2 14 (hex) (if ADD=0) | C2 14 (hex) (if ADD=0) | C2 20 15 (hex) |
| MX25L3205D | V | V | V | 15 (hex) | C2 15 (hex) (if ADD=0) | C2 15 (hex) (if ADD=0) | C2 20 16 (hex) |
| MX25L6405D | V | V | V | 16 (hex) | C2 16 (hex) (if ADD=0) | C2 16 (hex) (if ADD=0) | C2 20 17 (hex) |

Table 1. Additional Feature Comparison

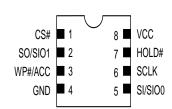


PIN CONFIGURATIONS

16-PIN SOP (300mil)

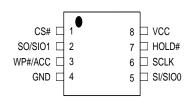


8-LAND WSON (8x6mm, 6x5mm) for MX25Lxx05D



MX25L1605D MX25L3205D MX25L6405D

8-PIN SOP (200mil, 150mil)



8-PIN PDIP (300mil)

| 1 2 3 | 8 7 6 | |
|-------------|-------------|-----------|
| 4 | 5 | □ SI/SIO0 |

PACKAGE OPTIONS

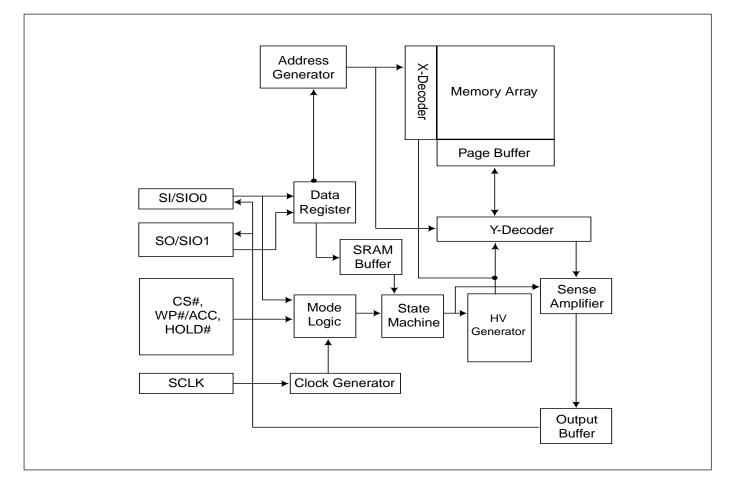
| | 16M | 32M | 64M |
|---------------|-----|-----|-----|
| 150mil 8-SOP | V | | |
| 200mil 8-SOP | V | V | |
| 300mil 16-SOP | V | V | V |
| 300mil 8-PDIP | V | V | |
| 6x5mm WSON | V | V | |
| 8x6mm WSON | | | V |
| | | | |

PIN DESCRIPTION

| SYMBOL | DESCRIPTION |
|---------|--|
| CS# | Chip Select |
| SI/SIO0 | Serial Data Input (for 1 x I/O)/ Serial Data |
| | Input & Output (for 2xI/O read mode) |
| SO/SIO1 | Serial Data Output (for 1 x I/O)/ Serial |
| | Data Input & Output (for 2xI/O read mode) |
| SCLK | Clock Input |
| WP#/ACC | Write protection: connect to GND; |
| | 11.0~11.5V for program/erase |
| | acceleration: connect to 11.0~11.5V |
| HOLD# | Hold, to pause the device without |
| | deselecting the device |
| VCC | + 3.3V Power Supply |
| GND | Ground |



BLOCK DIAGRAM





DATA PROTECTION

The MX25L1605D/3205D/6405D is designed to offer protection against accidental erasure or programming caused by spurious system level signals that may exist during power transition. During power up the device automatically resets the state machine in the Read mode. In addition, with its control register architecture, alteration of the memory contents only occurs after successful completion of specific command sequences. The device also incorporates several features to prevent inadvertent write cycles resulting from VCC power-up and power-down transition or system noise.

- Power-on reset and tPUW: to avoid sudden power switch by system power supply transition, the power-on reset and tPUW (internal timer) may protect the Flash.
- Valid command length checking: The command length will be checked whether it is at byte base and completed on byte boundary.
- Write Enable (WREN) command: WREN command is required to set the Write Enable Latch bit (WEL) before other command to change data. The WEL bit will return to reset stage under following situation:
 Power-up
 - Write Disable (WRDI) command completion
 - Write Status Register (WRSR) command completion
 - Page Program (PP) command completion
 - Continuously Program mode (CP) instruction completion
 - Sector Erase (SE) command completion
 - Block Erase (BE) command completion
 - Chip Erase (CE) command completion
 - Write Read-lock Bit (WRLB) instruction completion
- Deep Power Down Mode: By entering deep power down mode, the flash device also is under protected from writing all commands except Release from deep power down mode command (RDP) and Read Electronic Signature command (RES).
- Advanced Security Features: there are some protection and securuity features which protect content from inadvertent write and hostile access.

I. Block lock protection

- The Software Protected Mode (SPM) use (BP3, BP2, BP1, BP0) bits to allow part of memory to be protected as read only. The proected area definition is shown as table of "Protected Area Sizes", the protected areas are more flexible which may protect various area by setting value of BP0-BP3 bits.

Please refer to table of "protected area sizes".

- The Hardware Proteced Mode (HPM) use WP#/ACC to protect the (BP3, BP2, BP1, BP0) bits and SRWD bit.



Table 2. Protected Area Sizes

| | Statu | s bit | | Protect Level | | | | |
|-----|-------|-------|-----|------------------------------|------------------------------|--------------------------------|--|--|
| BP3 | BP2 | BP1 | BP0 | 16Mb | 32Mb | 64Mb | | |
| 0 | 0 | 0 | 0 | 0(none) | 0(none) | 0(none) | | |
| 0 | 0 | 0 | 1 | 1(1block, block 31th) | 1(1block, block 63th) | 1(2blocks, block 126th-127th) | | |
| 0 | 0 | 1 | 0 | 2(2blocks, block 30th-31th) | 2(2blocks, block 62th-63th) | 2(4blocks, block 124th-127th) | | |
| 0 | 0 | 1 | 1 | 3(4blocks, block 28th-31th) | 3(4blocks, block 60th-63th) | 3(8blocks, block 120th-127th) | | |
| 0 | 1 | 0 | 0 | 4(8blocks, block 24th-31th) | 4(8blocks, block 56th-63th) | 4(16blocks, block 112th-127th) | | |
| 0 | 1 | 0 | 1 | 5(16blocks, block 16th-31th) | 5(16blocks, block 48th-63th) | 5(32blocks, block 96th-127th) | | |
| 0 | 1 | 1 | 0 | 6(32blocks, all) | 6(32blocks, block 32th-63th) | 6(64blocks,block 64th-127th) | | |
| 0 | 1 | 1 | 1 | 7(32blocks, all) | 7(64blocks, all) | 7(128blocks, all) | | |
| 1 | 0 | 0 | 0 | 8(32blocks, all) | 8(64blocks, all) | 8(128blocks, all) | | |
| 1 | 0 | 0 | 1 | 9(32blocks, all) | 9(32blocks, block 0th-31th) | 9(64blocks, block 0th-63th) | | |
| 1 | 0 | 1 | 0 | 10(16blocks, block 0th-15th) | 10(48blocks, block 0th-47th) | 10(96blocks, block 0th-95th) | | |
| 1 | 0 | 1 | 1 | 11(24blocks, block 0th-23th) | 11(56blocks, block 0th-55th) | 11(112blocks, block 0th-111th) | | |
| 1 | 1 | 0 | 0 | 12(28blocks, block 0th-27th) | 12(60blocks, block 0th-59th) | 12(120blocks, block 0th-119th) | | |
| 1 | 1 | 0 | 1 | 13(30blocks, block 0th-29th) | 13(62blocks, block 0th-61th) | 13(124blocks, block 0th-123th) | | |
| 1 | 1 | 1 | 0 | 14(31blocks, block 0th-30th) | 14(63blocks, block 0th-62th) | 14(126blocks, block 0th-125th) | | |
| 1 | 1 | 1 | 1 | 15(32blocks, all) | 15(64blocks, all) | 15(128blocks, all) | | |

II. Additional 512-bit secured OTP for unique identifier: to provide 512-bit one-time program area for setting device unique serial number - Which may be set by factory or system customer. Please refer to table 3. 512-bit secured OTP definition.

- Security register bit 0 indicates whether the chip is locked by factory or not.

- To program the 512-bit secured OTP by entering 512-bit secured OTP mode (with ENSO command), and going through normal program procedure, and then exiting 512-bit secured OTP mode by writing EXSO command.

- Customer may lock-down the customer lockable secured OTP by writing WRSCUR (write security register) command to set customer lock-down bit1 as "1". Please refer to table of "security register definition" for security register bit definition and table of "512-bit secured OTP definition" for address range definition.

- Note: Once lock-down whatever by factory or customer, it cannot be changed any more. While in 512-bit secured OTP mode, array access is not allowed.

Table 3. 512-bit Secured OTP Definition

| Address range | Size | Standard | Customer Lock |
|---------------|---------|--------------------------------|------------------------|
| | | Factory Lock | |
| xxxx00~xxxx0F | 128-bit | ESN (electrical serial number) | |
| | | | Determined by customer |
| xxxx10~xxxx3F | 384-bit | N/A | |

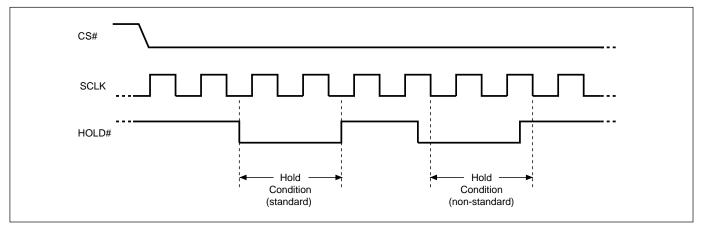


HOLD FEATURES

HOLD# pin signal goes low to hold any serial communications with the device. The HOLD feature will not stop the operation of write status register, programming, or erasing in progress.

The operation of HOLD requires Chip Select(CS#) keeping low and starts on falling edge of HOLD# pin signal while Serial Clock (SCLK) signal is being low (if Serial Clock signal is not being low, HOLD operation will not start until Serial Clock signal being low). The HOLD condition ends on the rising edge of HOLD# pin signal while Serial Clock(SCLK) signal is being low (if Serial Clock signal is not being low, HOLD operation will not end until Serial Clock being low), see Figure 1.





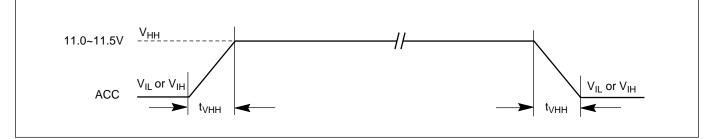
The Serial Data Output (SO) is high impedance, both Serial Data Input (SI) and Serial Clock (SCLK) are don't care during the HOLD operation. If Chip Select (CS#) drives high during HOLD operation, it will reset the internal logic of the device. To re-start communication with chip, the HOLD# must be at high and CS# must be at low.

PROGRAM/ERASE ACCELERATION

To activate the program/erase acceleration function requires ACC pin connecting to 11.0~11.5V voltage (see Figure 2), and then to be followed by the normal program/erase process. By utilizing the program/erase acceleration operation, the performances are improved as shown on table of "ERASE AND PROGRAM PERFORMACE".

After power-up ready, it should wait 10ms at least to apply VHH(11.0~11.5V) on the WP#/ACC pin.

Figure 2. ACCELERATED PROGRAM TIMING DIAGRAM



Note: tVHH (VHH Rise and Fall Time) min. 250ns



Table 4. COMMAND DEFINITION

| COMMAND | WREN | WRDI | RDID (read | RDSR | WRSR | READ | FAST | | SE (sector |
|-------------|--------------|-------------------|----------------|-------------|-------------|-------------|-------------|------------|------------|
| (byte) | (write | (write | identification | (read | (write | (read data) | READ | x I/O read | erase) |
| , | enable) | disable) |) | status | status | . , | (fast read | command) | |
| | | | | register) | register) | | data) | note1 | |
| 1st byte | 06 (hex) | 04 (hex) | 9F (hex) | 05 (hex) | 01 (hex) | 03 (hex) | 0B (hex) | BB (hex) | 20 (hex) |
| 2nd byte | | | | | | AD1 | AD1 | ADD(2) | AD1 |
| 3rd byte | | | | | | AD2 | AD2 | ADD(2) & | AD2 |
| | | | | | | | | Dummy(2) | |
| 4th byte | | | | | | AD3 | AD3 | | AD3 |
| 5th byte | | | | | | | Dummy | | |
| Action | sets the | resets the | outputs | to read out | to write | n bytes | n bytes | n bytes | to erase |
| | (WEL) | (WEL) | JEDEC ID: | the values | new values | read out | read out | read out | the |
| | write | write | 1-byte | of the | to the | until CS# | until CS# | by 2 x I/O | selected |
| | enable | enable | manufactur | status | status | goes high | goes high | until CS# | sector |
| | latch bit | latch bit | er ID & 2- | register | register | | | goes high | |
| | | | byte device | U | U | | | 0 0 | |
| | | | ID | | | | | | |
| Note 1: The | count base | e is 4-bit for | ADD(2) and [| Dummy(2) b | ecause of 2 | x I/O. And | he MSB is o | on SI/SIO0 | which is |
| | om 1 x I/O c | | | | | | | | |
| COMMAND | | CE (chip | PP (Page | CP | DP (Deep | RDP | RES (read | REMS | REMS2 |
| (byte) | erase) | erase) | program) | (Continuo- | power | (Release | electronic | (read | (read ID |
| | | | | usly | down) | from deep | ID) | electronic | for 2x I/O |
| | | | | program | , | , power | , | manufactu- | mode) |
| | | | | mode) | | down) | | rer & | , |
| | | | | / | | , | | device ID) | |
| 1st byte | D8 (hex) | 60 or C7 (hex) | 02 (hex) | AD (hex) | B9 (hex) | AB (hex) | AB (hex) | 90 (hex) | EF (hex) |
| 2nd byte | AD1 | (HEX) | AD1 | AD1 | | | х | x | х |
| 3rd byte | AD2 | | AD2 | AD2 | | | X | x | x |
| 4th byte | AD3 | | AD3 | AD3 | | | x | ADD(note | ADD(note |
| -til byte | 100 | | 100 | 100 | | | ^ | 2) | 2) |
| 5th byte | | | | | | | | , | |
| Action | to erase | to erase | to program | continously | enters | release | to read out | outout the | output the |
| | the | whole chip | the selected | | | from deep | 1-byte | | manufactu- |
| | selected | | page | whole | power | power | device ID | rer ID & | rer ID & |
| | | | 1 | chip, the | down | down | | device ID | device ID |
| | block | | | | | | | | |
| | block | | | | mode | mode | | | |
| | block | | | address is | mode | mode | | | |
| | block | | | | | mode | | | |

| Note 2: ADD=00H will output the manufacturer ID first and ADD=01H will output device ID first | | | | | | |
|---|--|---|---|--|---|--|
| COMMAND | ENSO | EXSO | RDSCUR | WRSCUR | ESRY | DSRY |
| (byte) | (enter | (exit | (read | (write | (enable | (disable |
| | secured | secured | security | security | SO to | SO to |
| | OTP) | OTP) | register) | register) | output RY/BY#) | output RY/BY#) |
| 1st byte | B1 (hex) | C1 (hex) | 2B (hex) | 2F (hex) | 70 (hex) | 80 (hex) |
| 2nd byte | | | | | | |
| 3rd byte | | | | | | |
| 4th byte | | | | | | |
| 5th byte | | | | | | |
| Action | to enter the 512-bit secured OTP mode | to exit the 512-bit secured OTP mode | to read value of security register | to set the lock-down bit as "1" (once lock- down, cannot be updated) | to enable SO to output RY/BY# during CP mode | to disable SO to output RY/BY# during CP mode |

Note 3: It is not recommoded to adopt any other code not in the command definition table, which will potentially enter the hidden mode.



Table 5-1. Memory Organization (16Mb)

| Block | Sector Address Range | | | | |
|----------|----------------------|--------------|--------------|--|--|
| DIOCK | 511 | 1FF000h | 1FFFFFh | | |
| 31 | : | : | : | | |
| | 496 | 1F0000h | 1F0FFFh | | |
| | 495 | 1EF000h | 1EFFFFh | | |
| 30 | +35 | : | : | | |
| 00 | : | : 1E0000h | : 1E0FFFh | | |
| | 479 | 1DF000h | 1DFFFFh | | |
| 29 | | · · · | | | |
| | : | : 1D0000h | : 1D0FFFh | | |
| | 463 | 1CF000h | 1CFFFFh | | |
| 28 | - +05 | · · | | | |
| 20 | : 448 | : 1C0000h | : 1C0FFFh | | |
| | 440 | | | | |
| 27 | 447 | 1BF000h | 1BFFFFh · | | |
| 21 | : | : | | | |
| | 432 | 1B0000h | 1B0FFFh | | |
| | 431 | 1AF000h | 1AFFFFh | | |
| 26 | <u> </u> | | | | |
| | 416 | 1A0000h | 1A0FFFh | | |
| | 415 | 19F000h | 19FFFFh | | |
| 25 | : | : | : | | |
| | 400 | 190000h | 190FFFh | | |
| | 399 | 18F000h | 18FFFFh | | |
| 24 | ÷ | : | : | | |
| | 384 | 180000h | 180FFFh | | |
| | 383 | 17F000h | 17FFFFh | | |
| 23 | : | - | | | |
| | 368 | 170000h | 170FFFh | | |
| | 367 | 16F000h | 16FFFFh | | |
| 22 | : | : | : | | |
| | 352 | 160000h | 160FFFh | | |
| | 351 | 15F000h | 15FFFFh | | |
| 21 | | | | | |
| <u> </u> | <u>:</u> 336 | : | | | |
| | | 150000h | 150FFFh | | |
| 20 | 335 | 14F000h | 14FFFFh | | |
| 20 | : | : | | | |
| | 320 | 140000h | 140FFFh | | |
| 40 | 319 | 13F000h | 13FFFFh | | |
| 19 | | | : | | |
| | 304 | 130000h | 130FFFh | | |
| | 303 | 12F000h | 12FFFFh | | |
| 18 | ÷ | : | : | | |
| | 288 | 120000h | 120FFFh | | |
| | 287 | 11F000h | 11FFFFh | | |
| 17 | : | : | : | | |
| | 272 | 110000h | 110FFFh | | |
| | 271 | 10F000h | 10FFFFh | | |
| 16 | : | : | : | | |
| - | . 256 | 100000h | 100FFFh | | |
| | 200 | 10000011 | 1001111 | | |

| Block | Sector | Address Range | | | |
|----------|--------|---------------|--------------------|--|--|
| | 255 | 0FF000h | 0FFFFFh | | |
| 15 | : | : | | | |
| | . 240 | 0F0000h | 0F0FFFh | | |
| | 239 | 0EF000h | 0EFFFFh | | |
| 14 | - 233 | · · | · | | |
| | : | : | | | |
| | 224 | 0E0000h | 0E0FFFh 0DFFFFh | | |
| 13 | 223 | 0DF000h | UDFFFFN · | | |
| 13 | : | : | : | | |
| | 208 | 0D0000h | 0D0FFFh | | |
| 10 | 207 | 0CF000h | 0CFFFFh | | |
| 12 | : | : | | | |
| | 192 | 0C0000h | 0C0FFFh | | |
| | 191 | 0BF000h | 0BFFFFh | | |
| 11 | ÷ | | | | |
| | 176 | 0B0000h | 0B0FFFh | | |
| | 175 | 0AF000h | 0AFFFFh | | |
| 10 | : | : | : | | |
| | 160 | 0A0000h | 0A0FFFh | | |
| | 159 | 09F000h | 09FFFFh | | |
| 9 | | | | | |
| 9 | : | : | | | |
| | 144 | 090000h | 090FFFh | | |
| | 143 | 08F000h | 08FFFFh | | |
| 8 | : | : | | | |
| | 128 | 080000h | 080FFFh | | |
| | 127 | 07F000h | 07FFFFh | | |
| 7 | ÷ | : | ÷ | | |
| | 112 | 070000h | 070FFFh | | |
| | 111 | 06F000h | 06FFFFh | | |
| 6 | : | : | : | | |
| | 96 | 060000h | 060FFFh | | |
| | 95 | 05F000h | 05FFFFh | | |
| 5 | | | | | |
| 5 | : | : | | | |
| | 80 | 050000h | 050FFFh | | |
| | 79 | 04F000h | 04FFFFh | | |
| 4 | | | | | |
| L | 64 | 040000h | 040FFFh | | |
| | 63 | 03F000h | 03FFFFh | | |
| 3 | : | : | | | |
| | 48 | 030000h | 030FFFh | | |
| | 47 | 02F000h | 02FFFFh | | |
| 2 | : | : | : | | |
| | . 32 | 020000h | 020FFFh | | |
| | 31 | 01F000h | 01FFFFh | | |
| 1 | | | • | | |
| | : | | | | |
| | 16 | 010000h | 010FFFh | | |
| | 15 | 00F000h | 00FFFFh | | |
| | | | | | |
| | 4 | 004000h | 004FFFh | | |
| 0 | 3 | 003000h | 003FFFh | | |
| | 2 | 002000h | 002FFFh | | |
| | 1 | 001000h | 001FFFh | | |
| | 0 | 000000h | 000FFFh | | |
| | - | - | | | |



Table 5-2. Memory Organization (32Mb)

| Diack | Sector Address Range | | | | |
|-------|----------------------|--------------|--------------|--|--|
| Block | Sector 1023 | 3FF000h | 3FFFFFh | | |
| 63 | 1023 | 3FF000n | 3FFFFFN | | |
| 03 | : | : | : | | |
| | 1008 | 3F0000h | 3F0FFFh | | |
| | 1007 | 3EF000h | 3EFFFFh | | |
| 62 | | | | | |
| | 992 | 3E0000h | 3E0FFFh | | |
| | 991 | 3DF000h | 3DFFFFh | | |
| 61 | ÷ | | | | |
| | 976 | 3D0000h | 3D0FFFh | | |
| | 975 | 3CF000h | 3CFFFFh | | |
| 60 | | : | | | |
| | 960 | 3C0000h | 3C0FFFh | | |
| | 959 | 3BF000h | 3BFFFFh | | |
| 59 | | : | | | |
| | 944 | 3B0000h | 3B0FFFh | | |
| | 943 | 3AF000h | 3AFFFFh | | |
| 58 | : | : | : | | |
| | 928 | 3A0000h | 3A0FFFh | | |
| | 927 | 39F000h | 39FFFFh | | |
| 57 | : | : | : | | |
| • | 912 | 390000h | 390FFFh | | |
| | 912 | 38F000h | 38FFFFh | | |
| 56 | | | | | |
| 00 | : 896 | : 380000h | : 380FFFh | | |
| | 895 | 37F000h | 37FFFFh | | |
| 55 | | 37F00011 | | | |
| 55 | : | : | | | |
| | 880 | 370000h | 370FFFh | | |
| | 879 | 36F000h | 36FFFFh | | |
| 54 | | | : | | |
| | 864 | 360000h | 360FFFh | | |
| | 863 | 35F000h | 35FFFFh | | |
| 53 | | | ÷ | | |
| | 848 | 350000h | 350FFFh | | |
| | 847 | 34F000h | 34FFFFh | | |
| 52 | : | | | | |
| | 832 | 340000h | 340FFFh | | |
| | 831 | 33F000h | 33FFFFh | | |
| 51 | : | : | • | | |
| | 816 | 330000h | 330FFFh | | |
| | 815 | 32F000h | 32FFFFh | | |
| 50 | : | : | : | | |
| | 800 | : 320000h | : 320FFFh | | |
| | 800 | 320000h | | | |
| 40 | 799 | 31F000h | 31FFFFh | | |
| 49 | <u> </u> | : | : | | |
| | 784 | 310000h | 310FFFh | | |
| | 783 | 30F000h | 30FFFFh | | |
| 48 | : | | : | | |
| | 768 | 300000h | 300FFFh | | |

| Block | Sector | Address Range | | | |
|---------|--------|---------------|--------------------|--|--|
| | 767 | 2FF000h | 2FFFFFh | | |
| 47 | : | : | : | | |
| | 752 | 2F0000h | 2F0FFFh | | |
| | 751 | 2EF000h | 2EFFFFh | | |
| 46 | : | : | : | | |
| | 736 | 2E0000h | 2E0FFFh | | |
| | 735 | 2DF000h | 2DFFFFh | | |
| 45 | : | : | : | | |
| | 720 | 2D0000h | 2D0FFFh | | |
| | 719 | 2CF000h | 2CFFFFh | | |
| 44 | : | : | : | | |
| | : | : 2C0000h | : 2C0FFFh | | |
| | 704 | 2C00001 | 2COFFFN 2BFFFFh | | |
| 43 | 703 | 26F0000 | 200000 | | |
| 43 | : | : | | | |
| L | 688 | 2B0000h | 2B0FFFh | | |
| | 687 | 2AF000h | 2AFFFFh | | |
| 42 | | | | | |
| | 672 | 2A0000h | 2A0FFFh | | |
| | 671 | 29F000h | 29FFFFh | | |
| 41 | ÷ | ÷ | : | | |
| | 656 | 290000h | 290FFFh | | |
| | 655 | 28F000h | 28FFFFh | | |
| 40 | : | : | : | | |
| | 640 | 280000h | 280FFFh | | |
| | 639 | 27F000h | 27FFFFh | | |
| 39 | : | : | : | | |
| | 624 | 270000h | 270FFFh | | |
| | 623 | | | | |
| 38 | . 023 | 26F000h | 26FFFFh | | |
| 50 | : | : 260000h | | | |
| | 608 | 260000h | 260FFFh | | |
| 07 | 607 | 25F000h | 25FFFFh | | |
| 37 | : | : | | | |
| L | 592 | 250000h | 250FFFh | | |
| | 591 | 24F000h | 24FFFFh | | |
| 36 | : | | | | |
| | 576 | 240000h | 240FFFh | | |
| | 575 | 23F000h | 23FFFFh | | |
| 35 | : | i | : | | |
| | 560 | 230000h | 230FFFh | | |
| | 559 | 22F000h | 22FFFFh | | |
| 34 | : | : | : | | |
| | 544 | 220000h | 220FFFh | | |
| | 543 | 21F000h | 21FFFFh | | |
| 33 | | | | | |
| 33 | : | | | | |
| | 528 | 210000h | 210FFFh | | |
| 20 | 527 | 20F000h | 20FFFFh | | |
| 32 | : | : | : | | |
| | 512 | 200000h | 200FFFh | | |



| Block | Sector | Address Range 1FF000h 1FFFFh 1F0000h 1F0FFFh 1E0000h 1EFFFh 1E0000h 1E0FFFh 1E0000h 1E0FFFh 1DF000h 1DFFFFh 1DF000h 1DFFFFh 1D0000h 1D0FFFh 1CF000h 1CFFFFh 1C0000h 1C0FFFh 1C0000h 1C0FFFh 1C0000h 1BFFFFh 1B0000h 1BFFFFh 1AF000h 1AFFFFh 1A0000h 1A0FFFh 19F000h 19FFFFh 190000h 190FFFh 18F000h 18FFFFh 180000h 180FFFh | | |
|-------|--------|---|--------------|--|
| | 511 | 1FF000h | 1FFFFFh | |
| 31 | ÷ | ÷ | ÷ | |
| | 496 | 1F0000h | 1F0FFFh | |
| | 495 | 1EF000h | 1EFFFFh | |
| 30 | : | : | : | |
| | 480 | 1E0000h | 1E0FFFh | |
| | 479 | 1DF000h | 1DFFFFh | |
| 29 | ÷ | | ÷ | |
| | 464 | 1D0000h | 1D0FFFh | |
| | 463 | 1CF000h | 1CFFFFh | |
| 28 | ÷ | | ÷ | |
| | 448 | 1C0000h | 1C0FFFh | |
| | 447 | 1BF000h | 1BFFFFh | |
| 27 | ÷ | | ÷ | |
| | 432 | 1B0000h | 1B0FFFh | |
| | 431 | 1AF000h | 1AFFFFh | |
| 26 | : | | : | |
| | 416 | 1A0000h | 1A0FFFh | |
| | 415 | 19F000h | 19FFFFh | |
| 25 | : | : | : | |
| | 400 | 190000h | 190FFFh | |
| | 399 | 18F000h | 18FFFFh | |
| 24 | : | : | : | |
| | 384 | 180000h | 180FFFh | |
| | 383 | 17F000h | 17FFFFh | |
| 23 | : | : | : | |
| | 368 | 170000h | 170FFFh | |
| | 367 | 16F000h | 16FFFFh | |
| 22 | : | : | : | |
| | 352 | 160000h | 160FFFh | |
| | 351 | 15F000h | 15FFFFh | |
| 21 | : | : | : | |
| | 336 | 150000h | 150FFFh | |
| | 335 | 14F000h | 14FFFFh | |
| 20 | : | : | : | |
| | 320 | : 140000h | : 140FFFh | |
| | 319 | 13F000h | 13FFFFh | |
| 19 | : | : | : | |
| - | 304 | 130000h | 130FFFh | |
| | | | | |
| 18 | 303 | 12F000h | 12FFFFh · | |
| | : | 120000 | | |
| | 288 | 120000h | 120FFFh | |
| 17 | 287 | 11F000h | 11FFFFh · | |
| 17 | : | : | | |
| | 272 | 110000h | 110FFFh | |
| 10 | 271 | 10F000h | 10FFFFh | |
| 16 | : | : | : | |
| | 256 | 100000h | 100FFFh | |

| Block | Sector | Address Range | | | |
|-------|--|---------------|--------------|--|--|
| | | 0FF000h | 0FFFFFh | | |
| 15 | 200 | : | : | | |
| | 240 | 0F0000h | 0F0FFFh | | |
| | | | | | |
| | 239 | 0EF000h | 0EFFFFh | | |
| 14 | : | : | : | | |
| | 224 | 0E0000h | 0E0FFFh | | |
| | 223 | 0DF000h | 0DFFFFh | | |
| 13 | | | | | |
| | 208 | 0D0000h | 0D0FFFh | | |
| | 207 | 0CF000h | 0CFFFFh | | |
| 12 | : | : | : | | |
| | 192 | 0C0000h | 0C0FFFh | | |
| | | 0BF000h | 0BFFFFh | | |
| 11 | : | : | : | | |
| | 176 | | | | |
| | - | 0B0000h | 0B0FFFh | | |
| | 175 | 0AF000h | 0AFFFFh | | |
| 10 | | | | | |
| | 160 | 0A0000h | 0A0FFFh | | |
| | 159 | 09F000h | 09FFFFh | | |
| 9 | | | | | |
| | 144 | 090000h | 090FFFh | | |
| | 143 | 08F000h | 08FFFFh | | |
| 8 | : | : | : | | |
| | . 128 | 080000h | 080FFFh | | |
| | | 07F000h | 07FFFFh | | |
| 7 | | | • | | |
| l ' | : | : | | | |
| | | 070000h | 070FFFh | | |
| | 111 | 06F000h | 06FFFFh | | |
| 6 | 240 0F 239 0E 239 0E 223 0D 223 0D 223 0D 208 0E 207 0C 192 0C 191 0E 176 0E 175 0A 160 0A 159 09 144 09 143 08 128 08 127 07 112 07 111 06 96 06 95 05 111 06 30 03 112 07 111 06 128 08 127 07 111 06 30 05 79 04 32 02 31 01 15 00 16 01 15 00 16 | ÷ | : | | |
| | 96 | 060000h | 060FFFh | | |
| | 95 | 05F000h | 05FFFFh | | |
| 5 | : | : | : | | |
| | 80 | 050000h | 050FFFh | | |
| | | 04F000h | 04FFFFh | | |
| 4 | | : | : | | |
| | <u> </u> | | | | |
| | | 040000h | 040FFFh | | |
| | . 63 | 03F000h | 03FFFFh · | | |
| 3 | : | : | : | | |
| | 48 | 030000h | 030FFFh | | |
| | 47 | 02F000h | 02FFFFh | | |
| 2 | | | | | |
| | 32 | 020000h | 020FFFh | | |
| | | 01F000h | 01FFFFh | | |
| 1 | : | : | : | | |
| | 16 | : 010000h | : 010FFFh | | |
| | | | 00FFFFh | | |
| | - 15 | 00F000h | | | |
| | <u> </u> | : | : | | |
| | - | 004000h | 004FFFh | | |
| 0 | | 003000h | 003FFFh | | |
| | | 002000h | 002FFFh | | |
| | | 001000h | 001FFFh | | |
| | 0 | 000000h | 000FFFh | | |
| | | | | | |



Table 5-3. Memory Organization (64Mb)

| Block | Sector | Address Range | | | |
|-------|--------------|--------------------|--------------------|--|--|
| | 2047 | 7FF000h | 7FFFFFh | | |
| 127 | : | : | : | | |
| | . 2032 | 7F0000h | 7F0FFFh | | |
| | 2031 | 7EF000h | 7EFFFFh | | |
| 126 | : | : | : | | |
| | 2016 | 7E0000h | 7E0FFFh | | |
| | 2015 | 7DF000h | 7DFFFFh | | |
| 125 | : | : | : | | |
| | 2000 | 7D0000h | 7D0FFFh | | |
| | 1999 | 7CF000h | 7CFFFFh | | |
| 124 | : | : | : | | |
| | 1984 | 7C0000h | 7C0FFFh | | |
| | 1983 | 7BF000h | 7BFFFFh | | |
| 123 | : | : | : | | |
| | 1968 | 7B0000h | 7B0FFFh | | |
| | 1967 | 7AF000h | 7AFFFFh | | |
| 122 | : | : | : | | |
| | 1952 | 7A0000h | 7A0FFFh | | |
| | 1952 | 79F000h | 79FFFFh | | |
| 121 | | · 9F00011 | · | | |
| 121 | : | : 700000b | : 790FFFh | | |
| | 1936 1935 | 790000h 78F000h | | | |
| 120 | | · · | 78FFFFh · | | |
| 120 | : | : | : | | |
| | 1920 1919 | 780000h 77F000h | 780FFFh 77FFFFh | | |
| 119 | | · · | · · · | | |
| 110 | : 1904 | : 770000h | : 770FFFh | | |
| | | | | | |
| 110 | 1903 | 76F000h | 76FFFFh | | |
| 118 | : | : | : | | |
| | 1888 | 760000h | 760FFFh | | |
| | 1887 | 75F000h | 75FFFFh | | |
| 117 | ÷ | | | | |
| | 1872 | 750000h | 750FFFh | | |
| | 1871 | 74F000h | 74FFFFh | | |
| 116 | : | | : | | |
| | 1856 | 740000h | 740FFFh | | |
| | 1855 | 73F000h | 73FFFFh | | |
| 115 | : | | | | |
| | 1840 | 730000h | 730FFFh | | |
| | 1839 | 72F000h | 72FFFFh | | |
| 114 | ÷ | - | | | |
| | 1824 | 720000h | 720FFFh | | |
| | 1823 | 71F000h | 71FFFFh | | |
| 113 | : | | | | |
| | 1808 | 710000h | 710FFFh | | |
| | 1807 | 70F000h | 70FFFFh | | |
| 112 | : | : | : | | |
| | 1792 | 700000h | 700FFFh | | |
| | | | | | |

| Block | Sector | Address Range | | | |
|----------|--------------|--------------------|--------------------|--|--|
| | 1791 | 6FF000h | 6FFFFFh | | |
| 111 | : | ÷ | | | |
| | 1776 | 6F0000h | 6F0FFFh | | |
| | 1775 | 6EF000h | 6EFFFFh | | |
| 110 | : | : | : | | |
| | 1760 | 6E0000h | 6E0FFFh | | |
| | 1759 | 6DF000h | 6DFFFFh | | |
| 109 | : | : | : | | |
| | 1744 | 6D0000h | 6D0FFFh | | |
| | 1743 | 6CF000h | 6CFFFFh | | |
| 108 | | | | | |
| | 1728 | 6C0000h | 6C0FFFh | | |
| | 1727 | 6BF000h | 6BFFFFh | | |
| 107 | - | : | : | | |
| | 1712 | 6B0000h | 6B0FFFh | | |
| | 1711 | 6AF000h | 6AFFFFh | | |
| 106 | : | : | : | | |
| | 1696 | 6A0000h | 6A0FFFh | | |
| | 1695 | 69F000h | 69FFFFh | | |
| 105 | | | | | |
| 100 | : 1680 | : 690000h | : 690FFFh | | |
| | 1679 | 68F000h | 68FFFFh | | |
| 104 | | | | | |
| 104 | : | : 680000h | | | |
| | 1664 1663 | 680000h 67F000h | 680FFFh 67FFFFh | | |
| 103 | 1663 | 67F000n | | | |
| 103 | : | : | | | |
| | 1648 | 670000h | 670FFFh | | |
| 100 | 1647 | 66F000h | 66FFFFh | | |
| 102 | : | : | | | |
| | 1632 | 660000h | 660FFFh | | |
| | 1631 | 65F000h | 65FFFFh | | |
| 101 | : | <u> </u> | | | |
| | 1616 | 650000h | 650FFFh | | |
| | 1615 | 64F000h | 64FFFFh | | |
| 100 | | : | : | | |
| | 1600 | 640000h | 640FFFh | | |
| | 1599 | 63F000h | 63FFFFh | | |
| 99 | | : | | | |
| | 1584 | 630000h | 630FFFh | | |
| | 1583 | 62F000h | 62FFFFh | | |
| 98 | : | : | : | | |
| | 1568 | 620000h | 620FFFh | | |
| | 1567 | 61F000h | 61FFFFh | | |
| 97 | : | : | : | | |
| | 1552 | 610000h | 610FFFh | | |
| <u> </u> | 1551 | 60F000h | 60FFFFh | | |
| 96 | : | : | : | | |
| | : 1536 | : 600000h | : 600FFFh | | |
| | 1000 | 00000011 | 0001111 | | |



| Block | Sector | Addres | s Range |
|-------|-----------|--------------|--------------|
| | 1535 | 5FF000h | 5FFFFFh |
| 95 | : | : | : |
| | 1520 | 5F0000h | 5F0FFFh |
| | 1519 | 5EF000h | 5EFFFFh |
| 94 | ÷ | ÷ | : |
| | 1504 | 5E0000h | 5E0FFFh |
| | 1503 | 5DF000h | 5DFFFFh |
| 93 | : | : | : |
| | 1488 | 5D0000h | 5D0FFFh |
| | 1487 | 5CF000h | 5CFFFFh |
| 92 | | : | : |
| | 1472 | 5C0000h | 5C0FFFh |
| | 1471 | 5BF000h | 5BFFFFh |
| 91 | : | : | : |
| | 1456 | 5B0000h | 5B0FFFh |
| | 1455 | 5AF000h | 5AFFFFh |
| 90 | ÷ | ÷ | : |
| | 1440 | 5A0000h | 5A0FFFh |
| | 1439 | 59F000h | 59FFFFh |
| 89 | | ÷ | |
| | 1424 | 590000h | 590FFFh |
| | 1423 | 58F000h | 58FFFFh |
| 88 | : | : | : |
| | 1408 | 580000h | 580FFFh |
| | 1407 | 57F000h | 57FFFFh |
| 87 | : | | |
| | 1392 | 570000h | 570FFFh |
| | 1391 | 56F000h | 56FFFFh |
| 86 | : | : | : |
| | 1376 | 560000h | 560FFFh |
| | 1375 | 55F000h | 55FFFFh |
| 85 | : | : | : |
| | 1360 | 550000h | 550FFFh |
| | 1359 | 54F000h | 54FFFFh |
| 84 | : | : | : |
| | | 540000h | 540FFFh |
| | 1343 | 53F000h | 53FFFFh |
| 83 | : | : | : |
| | 1328 | 530000h | 530FFFh |
| | 1327 | 52F000h | 52FFFFh |
| 82 | : | : | ; |
| | : 1312 | : 520000h | : 520FFFh |
| | 1312 | 51F000h | 51FFFFh |
| 81 | | | |
| | : 1296 | 510000b | : 510FFFh |
| | | 510000h | |
| 80 | 1295 | 50F000h | 50FFFFh · |
| 00 | : | : | |
| | 1280 | 500000h | 500FFFh |

| Block | Sector | Addres | s Range |
|-------|-----------|--------------|--------------------|
| | 1279 | 4FF000h | 4FFFFFh |
| 79 | : | : | : |
| | 1264 | 4F0000h | 4F0FFFh |
| | 1263 | 4EF000h | 4EFFFFh |
| 78 | : | : | : |
| | 1248 | 4E0000h | 4E0FFFh |
| | 1240 | 4DF000h | 4DFFFFh |
| 77 | | - 4D1 00011 | · |
| | : 1232 | : 4D0000h | : 4D0FFFh |
| | 1232 | | 4D0FFFh 4CFFFFh |
| 76 | . 1231 | 4CF000h | 40FFFF0 |
| 70 | : | : | : |
| | 1216 | 4C0000h | 4C0FFFh |
| | 1215 | 4BF000h | 4BFFFFh |
| 75 | | | |
| | 1200 | 4B0000h | 4B0FFFh |
| | 1119 | 4AF000h | 4AFFFFh |
| 74 | | | |
| | 1184 | 4A0000h | 4A0FFFh |
| | 1183 | 49F000h | 49FFFFh |
| 73 | : | : | : |
| | 1168 | 490000h | 490FFFh |
| | 1167 | 490000h | 490FFFFh |
| 72 | | 46F00011 | 40FFFFII |
| 12 | : | : | : |
| | 1152 | 480000h | 480FFFh |
| 74 | 1151 | 47F000h | 47FFFFh |
| 71 | : | : | : |
| | 1136 | 470000h | 470FFFh |
| | 1135 | 46F000h | 46FFFFh |
| 70 | | ÷ | : |
| | 1120 | 460000h | 460FFFh |
| | 1119 | 45F000h | 45FFFFh |
| 69 | : | : | : |
| | | 450000h | 450FFFh |
| | 1104 | 44F000h | 44FFFFh |
| 68 | : | | : |
| | 1099 | : 110000h | : 440FFFh |
| | 1088 | 440000h | |
| 67 | 1087 | 43F000h | 43FFFFh · |
| 67 | : | : | |
| L | 1072 | 430000h | 430FFFh |
| | 1071 | 42F000h | 42FFFFh |
| 66 | : | : | : |
| | 1056 | 420000h | 420FFFh |
| | 1055 | 41F000h | 41FFFFh |
| 65 | : | : | : |
| | 1040 | 410000h | 410FFFh |
| | 1039 | 40F000h | 40FFFFh |
| 64 | : | : | : |
| | : | : 400000b | |
| | 1024 | 400000h | 400FFFh |



| Block | Sector | Addres | s Range |
|-------|--------|---------|---------|
| | 1023 | 3FF000h | 3FFFFFh |
| 63 | : | : | : |
| | 1008 | 3F0000h | 3F0FFFh |
| | 1007 | 3EF000h | 3EFFFFh |
| 62 | : | | : |
| | 992 | 3E0000h | 3E0FFFh |
| | 991 | 3DF000h | 3DFFFFh |
| 61 | : | | : |
| | 976 | 3D0000h | 3D0FFFh |
| | 975 | 3CF000h | 3CFFFFh |
| 60 | | | |
| | 960 | 3C0000h | 3C0FFFh |
| | 959 | 3BF000h | 3BFFFFh |
| 59 | | | : |
| | 944 | 3B0000h | 3B0FFFh |
| | 943 | 3AF000h | 3AFFFFh |
| 58 | : | - | : |
| | 928 | 3A0000h | 3A0FFFh |
| | 927 | 39F000h | 39FFFFh |
| 57 | | | : |
| | 912 | 390000h | 390FFFh |
| | 911 | 38F000h | 38FFFFh |
| 56 | : | | : |
| | 896 | 380000h | 380FFFh |
| | 895 | 37F000h | 37FFFFh |
| 55 | ÷ | | : |
| | 880 | 370000h | 370FFFh |
| | 879 | 36F000h | 36FFFFh |
| 54 | : | ÷ | : |
| | 864 | 360000h | 360FFFh |
| | 863 | 35F000h | 35FFFFh |
| 53 | : | | : |
| | 848 | 350000h | 350FFFh |
| | 847 | 34F000h | 34FFFFh |
| 52 | : | | |
| | 832 | 340000h | 340FFFh |
| | 831 | 33F000h | 33FFFFh |
| 51 | | : | |
| | 816 | 330000h | 330FFFh |
| | 815 | 32F000h | 32FFFFh |
| 50 | : | : | : |
| | 800 | 320000h | 320FFFh |
| | 799 | 31F000h | 31FFFFh |
| 49 | : | : | : |
| | 784 | 310000h | 310FFFh |
| | 783 | 30F000h | 30FFFFh |
| 48 | : | : | : |
| | | 300000h | 300FFFh |
| | | | |

| Block | Sector | Address Range | | | |
|-------|------------|---------------|--------------------|--|--|
| DIOCK | 767 | 2FF000h | 2FFFFFh | | |
| 47 | : | 2FF00011 | 26666 | | |
| | : | : 250000b | | | |
| | 752 | 2F0000h | 2F0FFFh 2EFFFFh | | |
| 46 | 751 | 2EF000h | 2277770 | | |
| 40 | : | : | | | |
| | 736 735 | 2E0000h | 2E0FFFh 2DFFFFh | | |
| 45 | - 735 | 2DF000h | | | |
| 45 | : | : | | | |
| | 720 | 2D0000h | 2D0FFFh | | |
| 44 | 719 | 2CF000h | 2CFFFFh | | |
| 44 | : | : | : | | |
| | 704 | 2C0000h | 2C0FFFh | | |
| 40 | 703 | 2BF000h | 2BFFFFh | | |
| 43 | : | | : | | |
| | 688 | 2B0000h | 2B0FFFh | | |
| | 687 | 2AF000h | 2AFFFFh | | |
| 42 | : | : | : | | |
| | 672 | 2A0000h | 2A0FFFh | | |
| | 671 | 29F000h | 29FFFFh | | |
| 41 | : | : | : | | |
| | 656 | 290000h | 290FFFh | | |
| | 655 | 28F000h | 28FFFFh | | |
| 40 | : | : | : | | |
| | . 640 | 280000h | 280FFFh | | |
| | 639 | 27F000h | 27FFFFh | | |
| 39 | : | : | : | | |
| | 624 | 270000h | 270FFFh | | |
| | 623 | 26F000h | 26FFFFh | | |
| 38 | | 20F00011 | 20FFFFII | | |
| | : 608 | : 260000h | | | |
| | | | 260FFFh | | |
| 37 | 607 | 25F000h | 25FFFFh | | |
| 37 | : | : | : | | |
| | 592 | 250000h | 250FFFh | | |
| | 591 | 24F000h | 24FFFFh | | |
| 36 | : | : | : | | |
| | 576 | 240000h | 240FFFh | | |
| 05 | 575 | 23F000h | 23FFFFh | | |
| 35 | : | | | | |
| | 560 | 230000h | 230FFFh | | |
| | 559 | 22F000h | 22FFFFh | | |
| 34 | : | | : | | |
| | 544 | 220000h | 220FFFh | | |
| | 543 | 21F000h | 21FFFFh | | |
| 33 | : | : | : | | |
| | 528 | 210000h | 210FFFh | | |
| | 527 | 20F000h | 20FFFFh | | |
| 32 | : | : | : | | |
| | 512 | 200000h | 200FFFh | | |
| | | 2000001 | 2001111 | | |



| Block | Sector | Addres | s Range |
|-------|----------|--------------|--------------|
| | 511 | 1FF000h | 1FFFFFh |
| 31 | : | ÷ | - |
| | 496 | 1F0000h | 1F0FFFh |
| | 495 | 1EF000h | 1EFFFFh |
| 30 | | | - |
| | 480 | 1E0000h | 1E0FFFh |
| | 479 | 1DF000h | 1DFFFFh |
| 29 | | : | : |
| | 464 | 1D0000h | 1D0FFFh |
| | 463 | 1CF000h | 1CFFFFh |
| 28 | - : | ÷ | ÷ |
| | 448 | 1C0000h | 1C0FFFh |
| | 447 | 1BF000h | 1BFFFFh |
| 27 | : | : | : |
| | 432 | 1B0000h | 1B0FFFh |
| | 431 | 1AF000h | 1AFFFFh |
| 26 | : | : | : |
| | 416 | 1A0000h | 1A0FFFh |
| | 415 | 19F000h | 19FFFFh |
| 25 | : | : | : |
| | 400 | 190000h | 190FFFh |
| | 399 | 18F000h | 18FFFFh |
| 24 | : | : | : |
| | 384 | 180000h | 180FFFh |
| | 383 | 17F000h | 17FFFFh |
| 23 | : | : | : |
| | 368 | 170000h | 170FFFh |
| | 367 | 16F000h | 16FFFFh |
| 22 | : | : | : |
| | | 160000h | 160FFFh |
| | 351 | 15F000h | 15FFFFh |
| 21 | | : | : |
| 21 | 336 | : 150000h | : 150FFFh |
| | 335 | 14F000h | 14FFFFh |
| 20 | | : | : |
| 20 | : 320 | : 140000h | : 140FFFh |
| | 319 | 13F000h | 13FFFFh |
| 19 | : | : | ; |
| | 304 | : 130000h | : 130FFFh |
| | | | |
| 10 | 303 | 12F000h | 12FFFFh · |
| 18 | : | : | |
| | 288 | 120000h | 120FFFh |
| 47 | 287 | 11F000h | 11FFFFh |
| 17 | | | |
| | 272 | 110000h | 110FFFh |
| | 271 | 10F000h | 10FFFFh |
| 16 | | | |
| | 256 | 100000h | 100FFFh |

| Diack | Castar | Sector Address Range | | | |
|-------|---------------|----------------------|--------------------|--|--|
| Block | Sector 255 | | s Range 0FFFFFh | | |
| 45 | 255 | 0FF000h | UFFFFFn | | |
| 15 | : | : | : | | |
| | 240 | 0F0000h | 0F0FFFh | | |
| | 239 | 0EF000h | 0EFFFFh | | |
| 14 | | | | | |
| | 224 | 0E0000h | 0E0FFFh | | |
| | 223 | 0DF000h | 0DFFFFh | | |
| 13 | | | | | |
| | 208 | 0D0000h | 0D0FFFh | | |
| | 207 | 0CF000h | 0CFFFFh | | |
| 12 | : | : | : | | |
| | 192 | 0C0000h | 0C0FFFh | | |
| | 191 | 0BF000h | 0BFFFFh | | |
| 11 | : | : | : | | |
| | 176 | 0B0000h | 0B0FFFh | | |
| | | | | | |
| 10 | 175 · | 0AF000h | 0AFFFFh · | | |
| 10 | : | : | : | | |
| | 160 | 0A0000h | 0A0FFFh | | |
| | 159 | 09F000h | 09FFFFh | | |
| 9 | | | | | |
| | 144 | 090000h | 090FFFh | | |
| | 143 | 08F000h | 08FFFFh | | |
| 8 | : | : | : | | |
| | 128 | 080000h | 080FFFh | | |
| | 127 | 07F000h | 07FFFFh | | |
| 7 | : | : | : | | |
| | 112 | 070000h | 070FFFh | | |
| | | | | | |
| | 111 | 06F000h | 06FFFFh | | |
| 6 | | ÷ | - | | |
| | 96 | 060000h | 060FFFh | | |
| | 95 | 05F000h | 05FFFFh | | |
| 5 | : | | : | | |
| | 80 | 050000h | 050FFFh | | |
| | 79 | 04F000h | 04FFFFh | | |
| 4 | : | : | : | | |
| | 64 | 040000h | 040FFFh | | |
| | 63 | 03F000h | 03FFFFh | | |
| 3 | | : | : | | |
| | | : 030000b | : 030FFFh | | |
| | 48 | 030000h | | | |
| _ | 47 | 02F000h | 02FFFFh | | |
| 2 | <u>:</u> | | | | |
| | 32 | 020000h | 020FFFh | | |
| | 31 | 01F000h | 01FFFFh | | |
| 1 | : | : | : | | |
| | 16 | 010000h | 010FFFh | | |
| | 15 | 00F000h | 00FFFFh | | |
| | : | : | : | | |
| | 4 | : 004000h | : 004FFFh | | |
| 0 | 3 | | | | |
| U | 2 | 003000h | 003FFFh | | |
| | | 002000h | 002FFFh | | |
| | 1 | 001000h | 001FFFh | | |
| | 0 | 000000h | 000FFFh | | |



DEVICE OPERATION

- 1. Before a command is issued, status register should be checked to ensure device is ready for the intended operation.
- 2. When incorrect command is inputted to this LSI, this LSI becomes standby mode and keeps the standby mode until next CS# falling edge. In standby mode, SO pin of this LSI should be High-Z.
- 3. When correct command is inputted to this LSI, this LSI becomes active mode and keeps the active mode until next CS# rising edge.
- 4. Input data is latched on the rising edge of Serial Clock(SCLK) and data shifts out on the falling edge of SCLK. The difference of Serial mode 0 and mode 3 is shown as Figure 3.
- 5. For the following instructions: RDID, RDSR, RDSCUR, READ, FAST_READ, 2READ, RES, REMS and REMS2 the shifted-in instruction sequence is followed by a data-out sequence. After any bit of data being shifted out, the CS# can be high. For the following instructions: WREN, WRDI, WRSR, SE, BE, CE, PP, CP, RDP, DP, ENSO, EXSO, and WRSCUR, the CS# must go high exactly at the byte boundary; otherwise, the instruction will be rejected and not executed.
- 6. During the progress of Write Status Register, Program, Erase operation, to access the memory array is neglected and not affect the current operation of Write Status Register, Program, Erase.

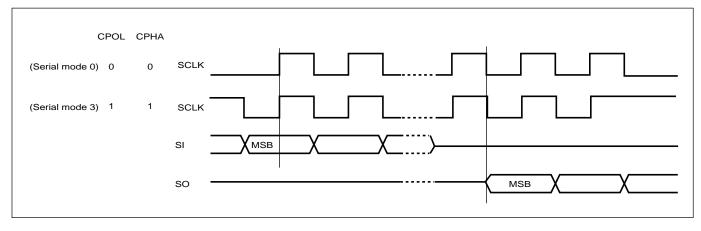


Figure 3. Serial Modes Supported

Note:

CPOL indicates clock polarity of Serial master, CPOL=1 for SCLK high while idle, CPOL=0 for SCLK low while not transmitting. CPHA indicates clock phase. The combination of CPOL bit and CPHA bit decides which Serial mode is supported.



COMMAND DESCRIPTION

(1) Write Enable (WREN)

The Write Enable (WREN) instruction is for setting Write Enable Latch (WEL) bit. For those instructions like PP, CP, SE, BE, CE, and WRSR, which are intended to change the device content, should be set every time after the WREN instruction setting the WEL bit.

The sequence of issuing WREN instruction is: CS# goes low-> sending WREN instruction code-> CS# goes high. (see Figure 12)

(2) Write Disable (WRDI)

The Write Disable (WRDI) instruction is for resetting Write Enable Latch (WEL) bit.

The sequence of issuing WRDI instruction is: CS# goes low-> sending WRDI instruction code-> CS# goes high. (see Figure 13)

The WEL bit is reset by following situations:

- Power-up
- Write Disable (WRDI) instruction completion
- Write Status Register (WRSR) instruction completion
- Page Program (PP) instruction completion
- Sector Erase (SE) instruction completion
- Block Erase (BE) instruction completion
- Chip Erase (CE) instruction completion
- Continuously program mode (CP) instruction completion

(3) Read Identification (RDID)

The RDID instruction is for reading the manufacturer ID of 1-byte and followed by Device ID of 2-byte. The MXIC Manufacturer ID is C2(hex), the memory type ID is 20(hex) as the first-byte device ID, and the individual device ID of second-byte ID are listed as table of "ID Definitions".

The sequence of issuing RDID instruction is: CS# goes low-> sending RDID instruction code -> 24-bits ID data out on SO -> to end RDID operation can use CS# to high at any time during data out. (see Figure. 14)

While Program/Erase operation is in progress, it will not decode the RDID instruction, so there's no effect on the cycle of program/erase operation which is currently in progress. When CS# goes high, the device is at standby stage.



(4) Read Status Register (RDSR)

The RDSR instruction is for reading Status Register Bits. The Read Status Register can be read at any time (even in program/erase/write status register condition) and continuously. It is recommended to check the Write in Progress (WIP) bit before sending a new instruction when a program, erase, or write status register operation is in progress.

The sequence of issuing RDSR instruction is: CS# goes low-> sending RDSR instruction code-> Status Register data out on SO (see Figure. 15)

The definition of the status register bits is as below:

WIP bit. The Write in Progress (WIP) bit, a volatile bit, indicates whether the device is busy in program/erase/write status register progress. When WIP bit sets to 1, which means the device is busy in program/erase/write status register progress. When WIP bit sets to 0, which means the device is not in progress of program/erase/write status register cycle.

WEL bit. The Write Enable Latch (WEL) bit, a volatile bit, indicates whether the device is set to internal write enable latch. When WEL bit sets to 1, which means the internal write enable latch is set, the device can accept program/erase/write status register instruction. When WEL bit sets to 0, which means no internal write enable latch; the device will not accept program/erase/write status register instruction. The program/erase command will be ignored and not affect value of WEL bit if it is applied to a protected memory area.

BP3, BP2, BP1, BP0 bits. The Block Protect (BP3, BP2, BP1, BP0) bits, non-volatile bits, indicate the protected area(as defined in table 1) of the device to against the program/erase instruction without hardware protection mode being set. To write the Block Protect (BP3, BP2, BP1, BP0) bits requires the Write Status Register (WRSR) instruction to be executed. Those bits define the protected area of the memory to against Page Program (PP), Sector Erase (SE), Block Erase (BE) and Chip Erase(CE) instructions (only if all Block Protect bits set to 0, the CE instruction can be executed).

Continuously Program Mode(CP mode) bit. The Continuously Program Mode bit indicates the status of CP mode, "0" indicates not in CP mode; "1" indicates in CP mode.

SRWD bit. The Status Register Write Disable (SRWD) bit, non-volatile bit, is operated together with Write Protection (WP#/ ACC) pin for providing hardware protection mode. The hardware protection mode requires SRWD sets to 1 and WP#/ACC pin signal is low stage. In the hardware protection mode, the Write Status Register (WRSR) instruction is no longer accepted for execution and the SRWD bit and Block Protect bits (BP3, BP2, BP1, BP0) are read only.

Status Register

| <u> </u> | | | | | | | |
|-------------------|-----------------|-------------------|------------------|-------------------|-------------------|-----------------|-----------------|
| bit7 | bit6 | bit5 | bit4 | bit3 | bit2 | bit1 | bit0 |
| SRWD | Continuously | BP3 | BP2 | BP1 | BP0 | WEL | WIP |
| (status register | program mode | (level of | (level of | (level of | (level of | (write enable | (write in |
| write protect) | (CP mode) | protected block) | protected block) | protected block) | protected block) | latch) | progress bit) |
| | 0 = normal | | | | | | 1= write |
| 1= status | program mode | (note1) | (note1) | (note1) | (note1) | 1= write enable | operation |
| register write | 1 = CP | (note r) | (note i) | (noter) | (note r) | 0= not write | 0= not in write |
| disable | mode(default 0) | | | | | enable | operation |
| Non- volatile bit | volatile bit | Non- volatile bit | Non-volatile bit | Non- volatile bit | Non- volatile bit | volatile bit | volatile bit |

note1: see the table "Protected Area Sizes"



(5) Write Status Register (WRSR)

The WRSR instruction is for changing the values of Status Register Bits. Before sending WRSR instruction, the Write Enable (WREN) instruction must be decoded and executed to set the Write Enable Latch (WEL) bit in advance. The WRSR instruction can change the value of Block Protect (BP3, BP2, BP1, BP0) bits to define the protected area of memory (as shown in table 1). The WRSR also can set or reset the Status Register Write Disable (SRWD) bit in accordance with Write Protection (WP#/ACC) pin signal. The WRSR instruction cannot be executed once the Hardware Protected Mode (HPM) is entered.

The sequence of issuing WRSR instruction is: CS# goes low-> sending WRSR instruction code-> Status Register data on SI-> CS# goes high. (see Figure 16)

The WRSR instruction has no effect on b6, b1, b0 of the status register.

The CS# must go high exactly at the byte boundary; otherwise, the instruction will be rejected and not executed. The selftimed Write Status Register cycle time (tW) is initiated as soon as Chip Select (CS#) goes high. The Write in Progress (WIP) bit still can be check out during the Write Status Register cycle is in progress. The WIP sets 1 during the tW timing, and sets 0 when Write Status Register Cycle is completed, and the Write Enable Latch (WEL) bit is reset.

Table 6. Protection Modes

| Mode | Status register condition | WP# and SRWD bit status | Memory |
|-----------------------------------|--|--|--|
| Software protection mode(SPM) | Status register can be written in (WEL bit is set to "1") and the SRWD, BP0-BP3 bits can be changed | WP#=1 and SRWD bit=0, or WP#=0 and SRWD bit=0, or WP#=1 and SRWD=1 | The protected area cannot be program or erase. |
| Hardware protection mode (HPM) | The SRWD, BP0-BP3 of status register bits cannot be changed | WP#=0, SRWD bit=1 | The protected area cannot be program or erase. |

Note:

1. As defined by the values in the Block Protect (BP3, BP2, BP1, BP0) bits of the Status Register, as shown in Table 1.

As the above table showing, the summary of the Software Protected Mode (SPM) and Hardware Protected Mode (HPM).

Software Protected Mode (SPM):

- When SRWD bit=0, no matter WP#/ACC is low or high, the WREN instruction may set the WEL bit and can change the values of SRWD, BP3, BP2, BP1, BP0. The protected area, which is defined by BP3, BP2, BP1, BP0, is at software protected mode (SPM).
- When SRWD bit=1 and WP#/ACC is high, the WREN instruction may set the WEL bit can change the values of SRWD, BP3, BP2, BP1, BP0. The protected area, which is defined by BP3, BP2, BP1, BP0, is at software protected mode (SPM)



Note: If SRWD bit=1 but WP#/ACC is low, it is impossible to write the Status Register even if the WEL bit has previously been set. It is rejected to write the Status Register and not be executed.

Hardware Protected Mode (HPM):

 When SRWD bit=1, and then WP#/ACC is low (or WP#/ACC is low before SRWD bit=1), it enters the hardware protected mode (HPM). The data of the protected area is protected by software protected mode by BP3, BP2, BP1, BP0 and hardware protected mode by the WP#/ACC to against data modification.

Note: to exit the hardware protected mode requires WP#/ACC driving high once the hardware protected mode is entered. If the WP#/ACC pin is permanently connected to high, the hardware protected mode can never be entered; only can use software protected mode via BP3, BP2, BP1, BP0.

(6) Read Data Bytes (READ)

The read instruction is for reading data out. The address is latched on rising edge of SCLK, and data shifts out on the falling edge of SCLK at a maximum frequency fR. The first address byte can be at any location. The address is automatically increased to the next higher address after each byte data is shifted out, so the whole memory can be read out at a single READ instruction. The address counter rolls over to 0 when the highest address has been reached.

The sequence of issuing READ instruction is: CS# goes low-> sending READ instruction code-> 3-byte address on SI -> data out on SO-> to end READ operation can use CS# to high at any time during data out. (see Figure. 17)

(7) Read Data Bytes at Higher Speed (FAST_READ)

The FAST_READ instruction is for quickly reading data out. The address is latched on rising edge of SCLK, and data of each bit shifts out on the falling edge of SCLK at a maximum frequency fC. The first address byte can be at any location. The address is automatically increased to the next higher address after each byte data is shifted out, so the whole memory can be read out at a single FAST_READ instruction. The address counter rolls over to 0 when the highest address has been reached.

The sequence of issuing FAST_READ instruction is: CS# goes low-> sending FAST_READ instruction code-> 3-byte address on SI-> 1-dummy byte address on SI->data out on SO-> to end FAST_READ operation can use CS# to high at any time during data out. (see Figure. 18)

While Program/Erase/Write Status Register cycle is in progress, FAST_READ instruction is rejected without any impact on the Program/Erase/Write Status Register current cycle.

(8) 2 x I/O Read Mode (2READ)

The 2READ instruction enable double throughput of Serial Flash in read mode. The address is latched on rising edge of SCLK, and data of every two bits (interleave on 2 I/O pins) shift out on the falling edge of SCLK at a maximum frequency fT. The first address byte can be at any location. The address is automatically increased to the next higher address after each byte data is shifted out, so the whole memory can be read out at a single 2READ instruction. The address counter rolls over to 0 when the highest address has been reached. Once writing 2READ instruction, the following address/dummy/ data out will perform as 2-bit instead of previous 1-bit.

The sequence of issuing 2READ instruction is: CS# goes low \rightarrow sending 2READ instruction \rightarrow 24-bit address interleave on SIO1 & SIO0 \rightarrow 8-bit dummy interleave on SIO1 & SIO0 \rightarrow data out interleave on SIO1 & SIO0 \rightarrow to end 2READ operation can use CS# to high at any time during data out (see Figure of 2 x I/O Read Mode Timing Waveform)



While Program/Erase/Write Status Register cycle is in progress, 2READ instruction is rejected without any impact on the Program/Erase/Write Status Register current cycle.

The 2 I/O only perform read operation. Program/Erase /Read ID/Read status/Read ID....operation do not support 2 I/O throughputs.

(9) Sector Erase (SE)

The Sector Erase (SE) instruction is for erasing the data of the chosen sector to be "1". The instruction is used for any 4K-byte sector. A Write Enable (WREN) instruction must execute to set the Write Enable Latch (WEL) bit before sending the Sector Erase (SE). Any address of the sector (see table 3) is a valid address for Sector Erase (SE) instruction. The CS# must go high exactly at the byte boundary (the latest eighth of address byte been latched-in); otherwise, the instruction will be rejected and not executed.

Address bits [Am-A12] (Am is the most significant address) select the sector address.

The sequence of issuing SE instruction is: CS# goes low -> sending SE instruction code-> 3-byte address on SI -> CS# goes high. (see Figure 22)

The self-timed Sector Erase Cycle time (tSE) is initiated as soon as Chip Select (CS#) goes high. The Write in Progress (WIP) bit still can be check out during the Sector Erase cycle is in progress. The WIP sets 1 during the tSE timing, and sets 0 when Sector Erase Cycle is completed, and the Write Enable Latch (WEL) bit is reset. If the page is protected by BP3, BP2, BP1, BP0 bits, the Sector Erase (SE) instruction will not be executed on the page.

(10) Block Erase (BE)

The Block Erase (BE) instruction is for erasing the data of the chosen block to be "1". The instruction is used for 64Kbyte sector erase operation. A Write Enable (WREN) instruction must execute to set the Write Enable Latch (WEL) bit before sending the Block Erase (BE). Any address of the block (see table 3) is a valid address for Block Erase (BE) instruction. The CS# must go high exactly at the byte boundary (the latest eighth of address byte been latched-in); otherwise, the instruction will be rejected and not executed.

The sequence of issuing BE instruction is: CS# goes low -> sending BE instruction code-> 3-byte address on SI -> CS# goes high. (see Figure 23)

The self-timed Block Erase Cycle time (tBE) is initiated as soon as Chip Select (CS#) goes high. The Write in Progress (WIP) bit still can be check out during the Sector Erase cycle is in progress. The WIP sets 1 during the tBE timing, and sets 0 when Sector Erase Cycle is completed, and the Write Enable Latch (WEL) bit is reset. If the page is protected by BP3, BP2, BP1, BP0 bits, the Block Erase (BE) instruction will not be executed on the page.

(11) Chip Erase (CE)

The Chip Erase (CE) instruction is for erasing the data of the whole chip to be "1". A Write Enable (WREN) instruction must execute to set the Write Enable Latch (WEL) bit before sending the Chip Erase (CE). Any address of the sector (see table 3) is a valid address for Chip Erase (CE) instruction. The CS# must go high exactly at the byte boundary(the latest eighth of address byte been latched-in); otherwise, the instruction will be rejected and not executed.

The sequence of issuing CE instruction is: CS# goes low-> sending CE instruction code-> CS# goes high. (see Figure 24)



The self-timed Chip Erase Cycle time (tCE) is initiated as soon as Chip Select (CS#) goes high. The Write in Progress (WIP) bit still can be check out during the Chip Erase cycle is in progress. The WIP sets 1 during the tCE timing, and sets 0 when Chip Erase Cycle is completed, and the Write Enable Latch (WEL) bit is reset. If the chip is protected by BP3, BP2, BP1, BP0 bits, the Chip Erase (CE) instruction will not be executed. It will be only executed when BP3, BP2, BP1, BP0 all set to "0".

(12) Page Program (PP)

The Page Program (PP) instruction is for programming the memory to be "0". A Write Enable (WREN) instruction must execute to set the Write Enable Latch (WEL) bit before sending the Page Program (PP). If the eight least significant address bits (A7-A0) are not all 0, all transmitted data which goes beyond the end of the current page are programmed from the start address if the same page (from the address whose 8 least significant address bits (A7-A0) are all 0). The CS# must keep during the whole Page Program cycle. The CS# must go high exactly at the byte boundary(the latest eighth of address byte been latched-in); otherwise, the instruction will be rejected and not executed. If more than 256 bytes are sent to the device, the data of the last 256-byte is programmed at the request page and previous data will be disregarded. If less than 256 bytes are sent to the device, the data is programmed at the request address of the page without effect on other address of the same page.

The sequence of issuing PP instruction is: CS# goes low-> sending PP instruction code-> 3-byte address on SI-> at least 1-byte on data on SI-> CS# goes high. (see Figure 20)

The self-timed Page Program Cycle time (tPP) is initiated as soon as Chip Select (CS#) goes high. The Write in Progress (WIP) bit still can be check out during the Page Program cycle is in progress. The WIP sets 1 during the tPP timing, and sets 0 when Page Program Cycle is completed, and the Write Enable Latch (WEL) bit is reset. If the page is protected by BP3, BP2, BP1, BP0 bits, the Page Program (PP) instruction will not be executed.

(13) Continuously program mode (CP mode)

The CP mode may enhance program performance by automatically increasing address to the next higher address after each byte data has been programmed.

The Continuously program (CP) instruction is for multiple byte program to Flash. A write Enable (WREN) instruction must execute to set the Write Enable Latch(WEL) bit before sending the Continuously program (CP) instruction. CS# requires to go high before CP instruction is executing. After CP instruction and address input, two bytes of data is input sequentially from MSB(bit7) to LSB(bit0). The first byte data will be programmed to the initial address range with A0=0 and second byte data with A0=1. If only one byte data is input, the CP mode will not process. If more than two bytes data are input, the additional data will be ignored and only two byte data are valid. The CP program instruction will be ignored and not affect the WEL bit if it is applied to a protected memory area. Any byte to be programmed should be in the erase state (FF) first. It will not roll over during the CP mode, once the last unprotected address has been reached, the chip will exit CP mode and reset write Enable Latch bit (WEL) as "0" and CP mode bit as "0". Please check the WIP bit status if it is not in write progress before entering next valid instruction. During CP mode, the valid commands are CP command (AD hex), WRDI command (04 hex), RDSR command (05 hex), RDPR command (A1 hex), and RDSCUR command (2B hex). And the WRDI command is valid after completion of a CP programming cycle, which means the WIP bit=0.

The sequence of issuing CP instruction is : CS# high to low-> sending CP instruction code-> 3-byte address on SI-> Data Byte on SI->CS# goes high to low-> sending CP instruction.....-> last desired byte programmed or sending Write Disable (WRDI) instruction to end CP mode-> sending RDSR instruction to verify if CP mode is ended. (see Figure of CP mode timing waveform)

Three methods to detect the completion of a program cycle during CP mode:

1) Software method-I: by checking WIP bit of Status Register to detect the completion of CP mode.



- 2) Software method-II: by waiting for a tBP time out to determine if it may load next valid command or not.
- 3) Hardware method: by writing ESRY (enable SO to output RY/BY#) instruction to detect the completion of a program cycle during CP mode. The ESRY instruction must be executed before CP mode execution. Once it is enable in CP mode, the CS# goes low will drive out the RY/BY# status on SO, "0" indicates busy stage, "1" indicates ready stage, SO pin outputs tri-state if CS# goes high. DSRY (disable SO to output RY/BY#) instruction to disable the SO to output RY/BY# and return to status register data output during CP mode. Please note that the ESRY/DSRY command are not accepted unless the completion of CP mode.

(14) Deep Power-down (DP)

The Deep Power-down (DP) instruction is for setting the device on the minimizing the power consumption (to entering the Deep Power-down mode), the standby current is reduced from ISB1 to ISB2). The Deep Power-down mode requires the Deep Power-down (DP) instruction to enter, during the Deep Power-down mode, the device is not active and all Write/Program/Erase instruction are ignored. When CS# goes high, it's only in standby mode not deep power-down mode. It's different from Standby mode.

The sequence of issuing DP instruction is: CS# goes low-> sending DP instruction code-> CS# goes high. (see Figure 25)

Once the DP instruction is set, all instruction will be ignored except the Release from Deep Power-down mode (RDP) and Read Electronic Signature (RES) instruction. (those instructions allow the ID being reading out). When Power-down, the deep power-down mode automatically stops, and when power-up, the device automatically is in standby mode. For RDP instruction the CS# must go high exactly at the byte boundary (the latest eighth bit of instruction code been latched-in); otherwise, the instruction will not executed. As soon as Chip Select (CS#) goes high, a delay of tDP is required before entering the Deep Power-down mode and reducing the current to ISB2.

(15) Release from Deep Power-down (RDP), Read Electronic Signature (RES)

The Release from Deep Power-down (RDP) instruction is terminated by driving Chip Select (CS#) High. When Chip Select (CS#) is driven High, the device is put in the Stand-by Power mode. If the device was not previously in the Deep Power-down mode, the transition to the Stand-by Power mode is immediate. If the device was previously in the Deep Power-down mode, though, the transition to the Stand-by Power mode is delayed by tRES2, and Chip Select (CS#) must remain High for at least tRES2(max), as specified in Table 6. Once in the Stand-by Power mode, the device waits to be selected, so that it can receive, decode and execute instructions.

RES instruction is for reading out the old style of 8-bit Electronic Signature, whose values are shown as table of ID Definitions. This is not the same as RDID instruction. It is not recommended to use for new design. For new design, please use RDID instruction. Even in Deep power-down mode, the RDP and RES are also allowed to be executed, only except the device is in progress of program/erase/write cycle; there's no effect on the current program/erase/write cycle in progress.

The sequence is shown as Figure 26,27.

The RES instruction is ended by CS# goes high after the ID been read out at least once. The ID outputs repeatedly if continuously send the additional clock cycles on SCLK while CS# is at low. If the device was not previously in Deep Power-down mode, the device transition to standby mode is immediate. If the device was previously in Deep Power-down mode, there's a delay of tRES2 to transit to standby mode, and CS# must remain to high at least tRES2(max). Once in the standby mode, the device waits to be selected, so it can be receive, decode, and execute instruction.

The RDP instruction is for releasing from Deep Power Down Mode.



(16) Read Electronic Manufacturer ID & Device ID (REMS), (REMS2)

The REMS & REMS2 instruction is an alternative to the Release from Power-down/Device ID instruction that provides both the JEDEC assigned manufacturer ID and the specific device ID.

The REMS & REMS2 instruction is very similar to the Release from Power-down/Device ID instruction. The instruction is initiated by driving the CS# pin low and shift the instruction code "90h" or "EFh" followed by two dummy bytes and one bytes address (A7~A0). After which, the Manufacturer ID for MXIC (C2h) and the Device ID are shifted out on the falling edge of SCLK with most significant bit (MSB) first as shown in figure 25. The Device ID values are listed in Table of ID Definitions. If the one-byte address is initially set to 01h, then the device ID will be read first and then followed by the Manufacturer ID. The Manufacturer and Device IDs can be read continuously, alternating from one to the other. The instruction is completed by driving CS# high.

Table 7. ID Definitions

| Command Type | MX25L1605D | | | MX25L3205D | | | MX25L6405D | | | |
|-----------------|-----------------|-------------|----------------|-----------------|-------------|----------------|-----------------|-------------|----------------|--|
| | Manufacturer ID | Memory type | Memory Density | Manufacturer ID | Memory type | Memory Density | Manufacturer ID | Memory type | Memory Density | |
| RDID (JEDEC ID) | C2 | 20 | 15 | C2 | 20 | 16 | C2 | 20 | 17 | |
| RES | Electronic ID | | Electronic ID | | | Electronic ID | | | | |
| NE J | | 14 | | 15 | | | 16 | | | |
| REMS/REMS2 | anufacturer ID | Device ID | | anufacturer ID | Device ID | | anufacturer ID | Device ID | | |
| NEIWIO/NEIWIOZ | C2 | 14 | | C2 | 15 | | C2 | 16 | | |

(17) Enter Secured OTP (ENSO)

The ENSO instruction is for entering the additional 512-bit secured OTP mode. The additional 512-bit secured OTP is independent from main array, which may use to store unique serial number for system identifier. After entering the Secured OTP mode, and then follow standard read or program, procedure to read out the data or update data. The Secured OTP data cannot be updated again once it is lock-down.

The sequence of issuing ENSO instruction is: CS# goes low-> sending ENSO instruction to enter Secured OTP mode -> CS# goes high.

Please note that WRSR/WRSCUR commands are not acceptable during the access of secure OTP region, once security OTP is lock down, only read related commands are valid.

(18) Exit Secured OTP (EXSO)

The EXSO instruction is for exiting the additional 512-bit secured OTP mode.

The sequence of issuing EXSO instruction is: CS# goes low-> sending EXSO instruction to exit Secured OTP mode-> CS# goes high.



(19) Read Security Register (RDSCUR)

The RDSCUR instruction is for reading the value of Security Register bits. The Read Security Register can be read at any time (even in program/erase/write status register/write security register condition) and continuously.

The sequence of issuing RDSCUR instruction is : CS# goes low-> send ing RDSCUR instruction -> Security Register data out on SO-> CS# goes high.

The definition of the Security Register bits is as below:

Secured OTP Indicator bit. The Secured OTP indicator bit shows the chip is locked by factory before ex-factory or not. When it is "0", it indicates non-factory lock; "1" indicates factory-lock.

Lock-down Secured OTP (LDSO) bit. By writing WRSCUR instruction, the LDSO bit may be set to "1" for customer lockdown purpose. However, once the bit is set to "1" (lock-down), the LDSO bit and the 512-bit Secured OTP area cannot be update any more. While it is in 512-bit secured OTP mode, array access is not allowed.

Table 8. Security Register Definition

| bit7 | bit6 | bit5 | bit4 | bit3 | bit2 | bit1 | bit0 |
|--------------|--------------|--------------|--------------|--------------|--------------|--|-------------------------------|
| x | х | х | x | х | x | Ìock-down | Secrured OTP indicator bit |
| reserved | reserved | reserved | reserved | reserved | reserved | 0 = not lock- down 1 = lock-down (cannot program/erase OTP) | factory lock |
| volatile bit | non-volatile bit | non-volatile bit |

(20) Write Security Register (WRSCUR)

The WRSCUR instruction is for changing the values of Security Register Bits. Unlike write status register, the WREN instruction is not required before sending WRSCUR instruction. The WRSCUR instruction may change the values of bit1 (LDSO bit) for customer to lock-down the 512-bit Secured OTP area. Once the LDSO bit is set to "1", the Secured OTP area cannot be updated any more.

The sequence of issuing WRSCUR instruction is :CS# goes low-> sending WRSCUR instruction -> CS# goes high.

The CS# must go high exactly at the boundary; otherwise, the instruction will be rejected and not executed.



POWER-ON STATE

The device is at below states when power-up:

- Standby mode (please note it is not deep power-down mode)
- Write Enable Latch (WEL) bit is reset

The device must not be selected during power-up and power-down stage unless the VCC achieves below correct level:

- VCC minimum at power-up stage and then after a delay of tVSL
- -GND at power-down

Please note that a pull-up resistor on CS# may ensure a safe and proper power-up/down level.

An internal power-on reset (POR) circuit may protect the device from data corruption and inadvertent data change during power up state. When VCC is lower than VWI (POR threshold voltage value), the internal logic is reset and the flash device has no response to any command.

For further protection on the device, after VCC reaching the VWI level, a tPUW time delay is required before the device is fully accessible for commands like write enable(WREN), page program (PP), Continuously Program (CP), sector erase(SE), chip erase(CE), WRSCUR and write status register(WRSR). If the VCC does not reach the VCC minimum level, the coperation is not guaranteed. The write, erase, and program command should be sent after the below time delay:

- tPUW after VCC reached VWI level

- tVSL after VCC reached VCC minimum level

The device can accept read command after VCC reached VCC minimum and a time delay of tVSL, even time of tPUW has not passed.

Please refer to the figure of "power-up timing".

Note:

- To stabilize the VCC level, the VCC rail decoupled by a suitable capacitor close to package pins is recommended.(generallyaround0.1uF)

- At power-down stage, the VCC drops below VWI level, all operations are disable and device has no response to any command. The data corruption might occur during the stage while a write, program, erase cycle is in progress.



ELECTRICAL SPECIFICATIONS

ABSOLUTE MAXIMUM RATINGS

| RATING | VALUE | |
|-------------------------------|------------------------------------|--|
| Ambient Operating Temperature | -40°C to 85°C for Industrial grade | |
| Storage Temperature | -55°C to 125°C | |
| Applied Input Voltage | -0.5V to 4.6V | |
| Applied Output Voltage | -0.5V to 4.6V | |
| VCC to Ground Potential | -0.5V to 4.6V | |

NOTICE:

- 1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is stress rating only and functional operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended period may affect reliability.
- 2. Specifications contained within the following tables are subject to change.
- 3. During voltage transitions, all pins may overshoot to 4.6V or -0.5V for period up to 20ns.
- 4. All input and output pins may overshoot to VCC+0.5V while VCC+0.5V is smaller than or equal to 4.6V.

Figure 4. Maximum Negative Overshoot Waveform

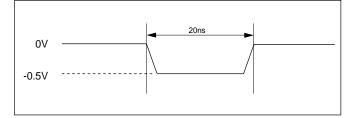
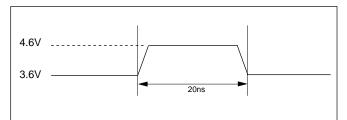


Figure 5. Maximum Positive Overshoot Waveform



CAPACITANCE TA = 25°C, f = 1.0 MHz

| SYMBOL | PARAMETER | MIN. | TYP | MAX. | UNIT | CONDITIONS |
|--------|--------------------|------|-----|------|------|------------|
| CIN | Input Capacitance | | | 6 | pF | VIN = 0V |
| COUT | Output Capacitance | | | 8 | pF | VOUT = 0V |



Figure 6. INPUT TEST WAVEFORMS AND MEASUREMENT LEVEL

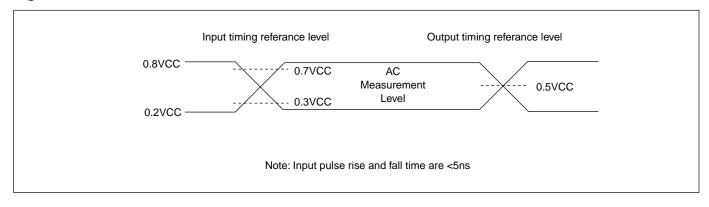


Figure 7. OUTPUT LOADING

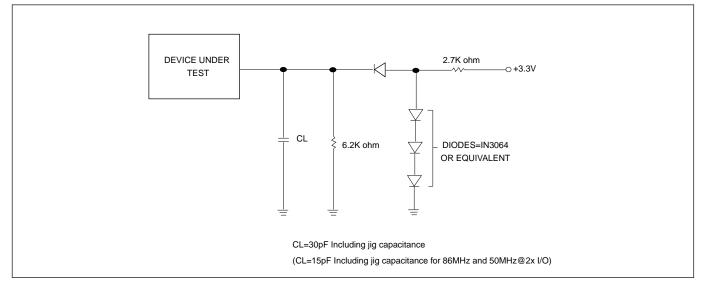




Table 9. DC CHARACTERISTICS

(Temperature = -40°C to 85°C for Industrial grade, VCC = 2.7V ~ 3.6V)

| SYMBOL | PARAMETER | NOTES | MIN. | TYP | MAX. | UNITS | TEST CONDITIONS |
|--------|----------------------|-------|---------|------|---------|-------|-------------------------------------|
| ILI | Input Load | 1 | | | ±2 | uA | VCC = VCC Max |
| | Current | | | | | | VIN = VCC or GND |
| ILO | Output Leakage | 1 | | | ±2 | uA | VCC = VCC Max |
| | Current | | | | | | VIN = VCC or GND |
| ILIHV | HV pin input Leakage | ; | | | 35 | uA | WP#/ACC=11.5V |
| | Current | | | | | | |
| ISB1 | VCC Standby | 1 | | | 20 | uA | VIN = VCC or GND |
| | Current | | | | | | CS# = VCC |
| ISB2 | Deep Power-down | | | | 20 | uA | VIN = VCC or GND |
| | Current | | | | | | CS# = VCC |
| ICC1 | VCC Read | 1 | | | 25 | mA | f=86MHz |
| | | | | | | | fT=50MHz (2 x I/O read) |
| | | | | | | | SCLK=0.1VCC/0.9VCC, SO=Open |
| | | | | | 20 | mA | f=66MHz |
| | | | | | | | SCLK=0.1VCC/0.9VCC, SO=Open |
| | | | | | 10 | mA | f=33MHz |
| | | | | | | | SCLK=0.1VCC/0.9VCC, SO=Open |
| ICC2 | VCC Program | 1 | | | 20 | mA | Program in Progress |
| | Current (PP) | | | | | | CS# = VCC |
| ICC3 | VCC Write Status | | | | 20 | mA | Program status register in progress |
| | Register (WRSR) | | | | | | CS#=VCC |
| | Current | | | | | | |
| ICC4 | VCC Sector Erase | 1 | | | 20 | mA | Erase in Progress |
| | Current (SE) | | | | | | CS#=VCC |
| ICC5 | VCC Chip Erase | 1 | | | 20 | mA | Erase in Progress |
| | Current (CE) | | | | | | CS#=VCC |
| VHH | Voltage for ACC Prog | gram/ | | 11.0 | 11.5 | V | VCC=2.7V~3.6V |
| | Erase Acceleration | | | | | | |
| VIL | Input Low Voltage | | -0.5 | | 0.3VCC | V | |
| VIH | Input High Voltage | | 0.7VCC | | VCC+0.4 | V | |
| VOL | Output Low Voltage | | | | 0.4 | V | IOL = 1.6mA |
| VOH | Output High Voltage | | VCC-0.2 | | | V | IOH = -100uA |



Table 10. AC CHARACTERISTICS

(Temperature = -40°C to 85°C for Industrial grade, VCC = 2.7V ~ 3.6V)

| Symbol | Alt. | Parameter | | | Min. | Тур. | Max. | Unit |
|----------|------|------------------------------------|---------------|---------------|-----------|------|-----------|------|
| fSCLK | fC | Clock Frequency for the following | instructions: | | 10KHz | | 86 | MHz |
| | | FAST_READ, PP, SE, BE, CE, D | | (Co | ndition:1 | 5pF) | | |
| | | WREN, WRDI, RDID, RDSR, WRS | SR | | | | 66 | MHz |
| | | | | | | (Co | ndition:3 | 0pF) |
| fRSCLK | fR | Clock Frequency for READ instruct | ctions | | 10KHz | | 33 | MHz |
| fTSCLK | fT | Clock Frequency for 2READ instru | uctions | | 10KHz | | 50 | MHz |
| | | | | | | (Co | ndition:1 | 5pF) |
| tCH(1) | tCLH | Clock High Time | | | 7 | | | ns |
| tCL(1) | tCLL | Clock Low Time | | | 7 | | | ns |
| tCLCH(2) | | Clock Rise Time (3) (peak to peak | x) | | 0.1 | | | V/ns |
| tCHCL(2) | | Clock Fall Time (3) (peak to peak) | | | 0.1 | | | V/ns |
| tSLCH | tCSS | CS# Active Setup Time (relative to | o SCLK) | | 5 | | | ns |
| tCHSL | | CS# Not Active Hold Time (relativ | e to SCLK) | | 5 | | | ns |
| tDVCH | tDSU | Data In Setup Time | | | 2 | | | ns |
| tCHDX | tDH | Data In Hold Time | | | 5 | | | ns |
| tCHSH | | CS# Active Hold Time (relative to | SCLK) | | 5 | | | ns |
| tSHCH | | CS# Not Active Setup Time (relati | ve to SCLK) | | 5 | | | ns |
| tSHSL | tCSH | CS# Deselect Time | | | 100 | | | ns |
| tSHQZ(2) | tDIS | Output Disable Time | 64Mb/ | 2.7V-3.6V | | | 10 | ns |
| | | | 32Mb/ | 3.0V-3.6V | | | 8 | ns |
| | | | 16Mb | | | | | |
| tCLQV | tV | Clock Low to Output Valid | 64Mb/ | 2.7V-3.6V | | | 10 | ns |
| | | | 32Mb/ | 3.0V-3.6V | | | 8 | ns |
| | | | 16Mb | | | | | |
| tCLQX | tHO | Output Hold Time | II | | 0 | | | ns |
| tHLCH | | HOLD# Setup Time (relative to SC | CLK) | | 5 | | | ns |
| tCHHH | | HOLD# Hold Time (relative to SCL | _K) | | 5 | | | ns |
| tHHCH | | HOLD Setup Time (relative to SCI | _K) | | 5 | | | ns |
| tCHHL | | HOLD Hold Time (relative to SCL) | <) | | 5 | | | ns |
| tHHQX(2) | tLZ | HOLD to Output Low-Z | 64Mb/ | 2.7V-3.6V | | | 10 | ns |
| | | | 32Mb/ | 3.0V-3.6V | | | 8 | ns |
| | | | 16Mb | | | | | |
| tHLQZ(2) | tHZ | HOLD# to Output High-Z | 64Mb/ | 2.7V-3.6V | | | 10 | ns |
| . , | | - | 32Mb/ | 3.0V-3.6V | | | 8 | ns |
| | | | 16Mb | | | | | |
| tWHSL(4) | | Write Protect Setup Time | II | | 20 | | | ns |
| tSHWL(4) | | Write Protect Hold Time | | | 100 | | | ns |
| tDP(2) | | CS# High to Deep Power-down Mo | ode | | | | 10 | us |
| tRES1(2) | | CS# High to Standby Mode without | | Signature Rea | d | | 8.8 | us |
| tRES2(2) | | CS# High to Standby Mode with E | | <u> </u> | | | 8.8 | us |



| Symbol | Alt. | Parameter | | Min. | Тур. | Max. | Unit |
|--------|------|----------------------------------|------|------|------|------|------|
| tW | | Write Status Register Cycle Time | | | 40 | 100 | ms |
| tBP | | Byte-Program | | | 9 | 300 | us |
| tPP | | Page Program Cycle Time | | | 1.4 | 5 | ms |
| tSE | | Sector Erase Cycle Time | | | 90 | 300 | ms |
| tBE | | Block Erase Cycle Time | | | 0.7 | 2 | S |
| tCE | | Chip Erase Cycle Time | 64Mb | | 50 | 80 | S |
| | | | 32Mb | | 25 | 50 | S |
| | | | 16Mb | | 14 | 30 | S |

Notes:

1. tCH + tCL must be greater than or equal to 1/ fC. For Fast Read, tCL/tCH=5.5/5.5. 2. Value guaranteed by characterization, not 100% tested in production.

3. Expressed as a slew-rate.

4. Only applicable as a constraint for a WRSR instruction when SRWD is set at 1.

5. Test condition is shown as Figure 6.



Table 11. Power-Up Timing and VWI Threshold

| Symbol | Parameter | Min. | Max. | Unit |
|---------|---------------------------------|------|------|------|
| tVSL(1) | VCC(min) to CS# low | 200 | | us |
| tPUW(1) | Time delay to Write instruction | 1 | 10 | ms |
| VWI(1) | Write Inhibit Voltage | 1.5 | 2.5 | V |

Note: 1. These parameters are characterized only.

INITIAL DELIVERY STATE

The device is delivered with the memory array erased: all bits are set to 1 (each byte contains FFh). The Status Register contains 00h (all Status Register bits are 0).



Figure 8. Serial Input Timing

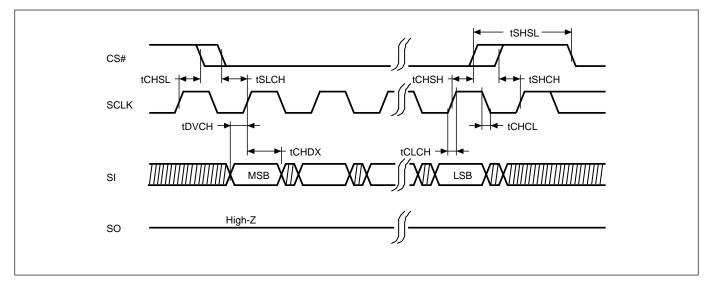


Figure 9. Output Timing

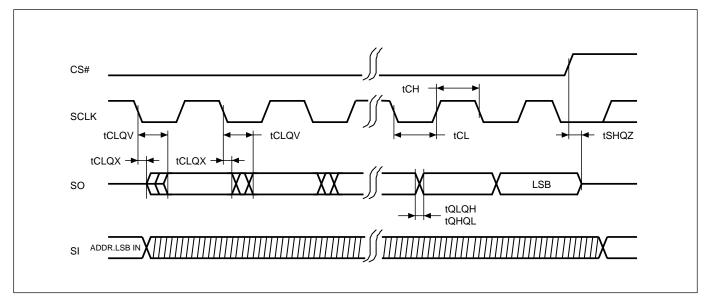
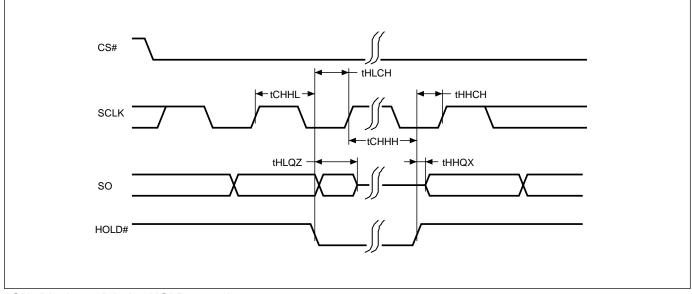
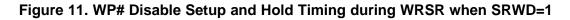




Figure 10. Hold Timing



* SI is "don't care" during HOLD operation.



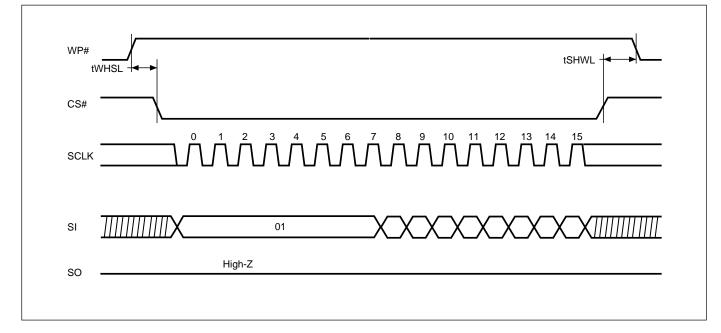




Figure 12. Write Enable (WREN) Sequence (Command 06)

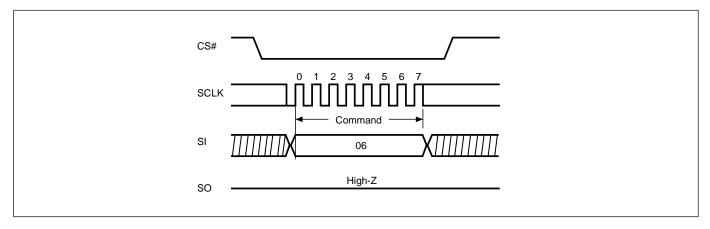
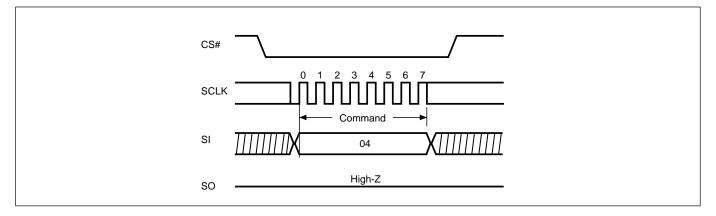
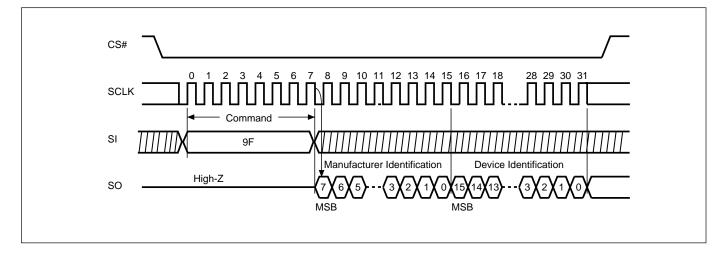


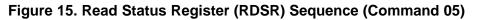
Figure 13. Write Disable (WRDI) Sequence (Command 04)











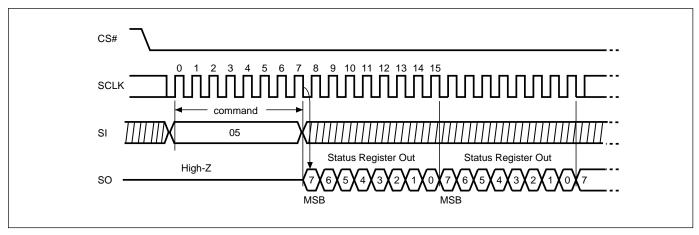
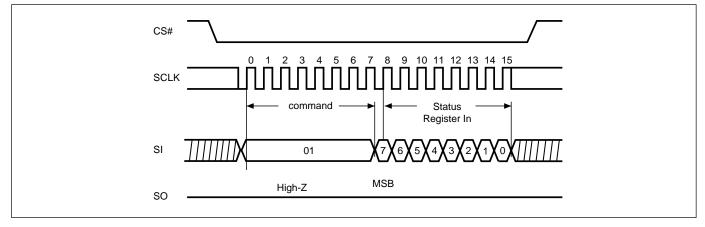


Figure 16. Write Status Register (WRSR) Sequence (Command 01)





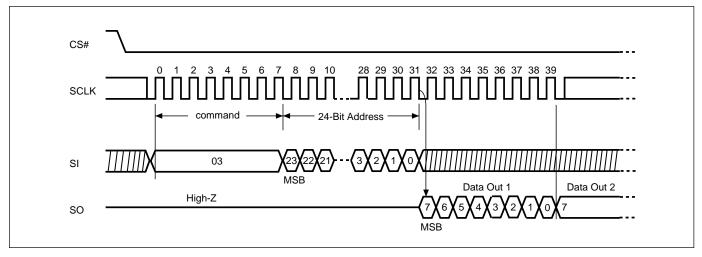
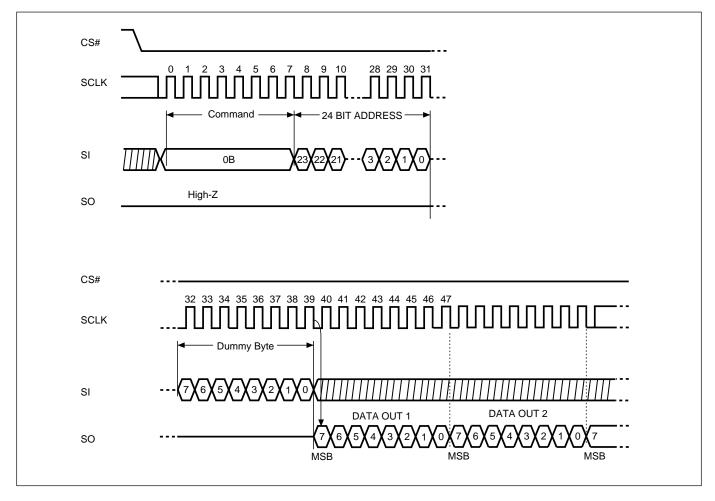




Figure 18. Read at Higher Speed (FAST_READ) Sequence (Command 0B)







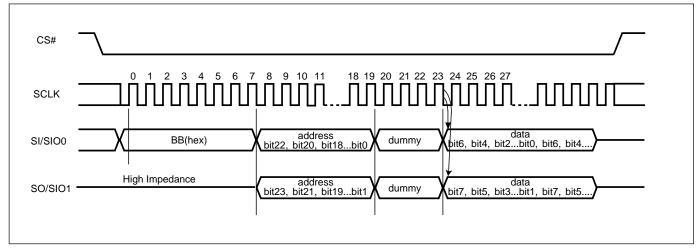


Figure 20. Page Program (PP) Sequence (Command 02)

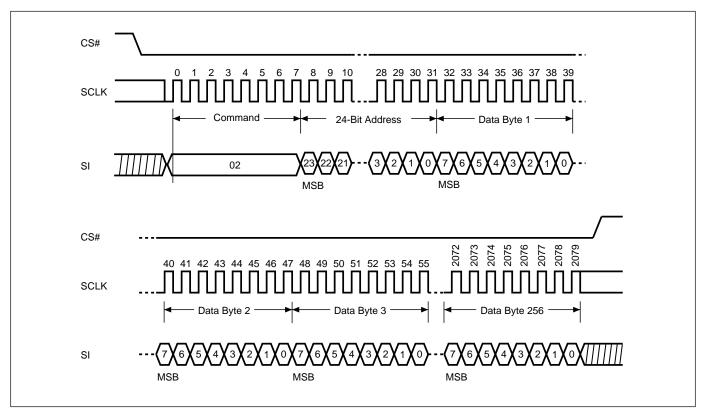
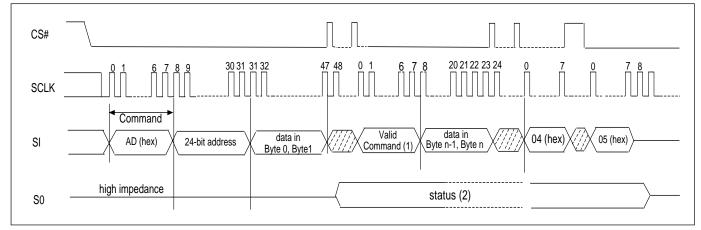




Figure 21. Continously Program (CP) Mode Sequence with Hardware Detection (Command AD)

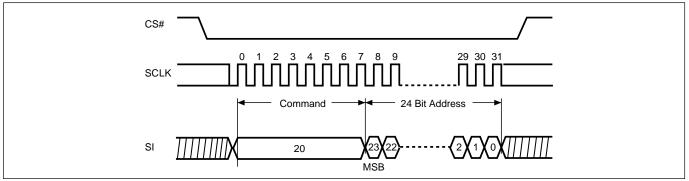


Note: (1) During CP mode, the valid commands are CP command (AD hex), WRDI command (04 hex), RDSR command (05 hex), RDPR command (A1 hex), and RDSCUR command (2B hex).

(2) Once an internal programming operation begins, CS# goes low will drive the status on the SO pin and CS# goes high will return the SO pin to tri-state.

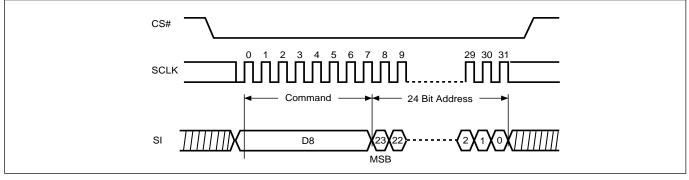
(3) To end the CP mode, either reaching the highest unprotected address or sending Write Disable (WRDI) command (04 hex) may achieve it and then it is recommended to send RDSR command (05 hex) to verify if CP mode is ended

Figure 22. Sector Erase (SE) Sequence (Command 20)



Note: SE command is 20(hex).

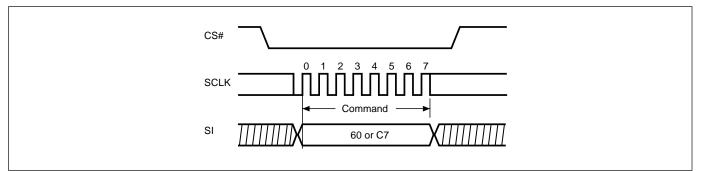
Figure 23. Block Erase (BE) Sequence (Command D8)



Note: BE command is D8(hex).



Figure 24. Chip Erase (CE) Sequence (Command 60 or C7)



Note: CE command is 60(hex) or C7(hex).

Figure 25. Deep Power-down (DP) Sequence (Command B9)

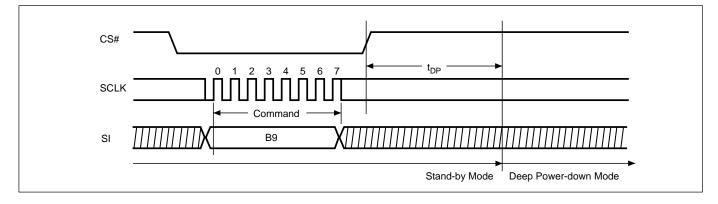
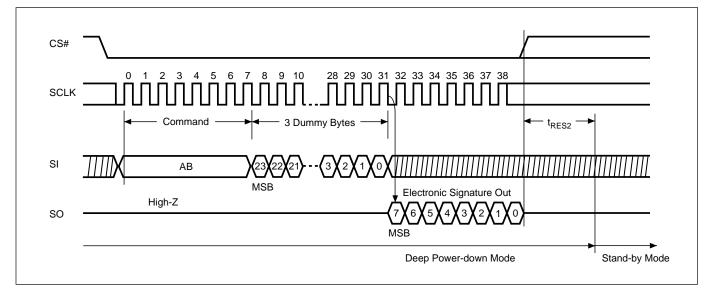
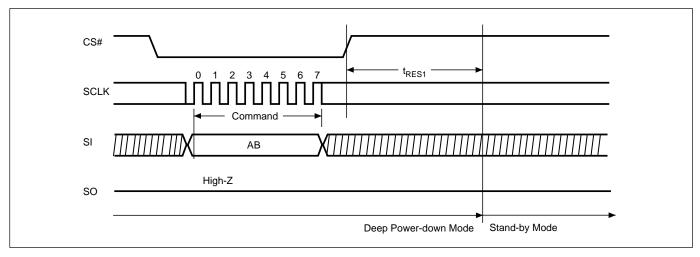


Figure 26. Release from Deep Power-down and Read Electronic Signature (RES) Sequence (Command AB)

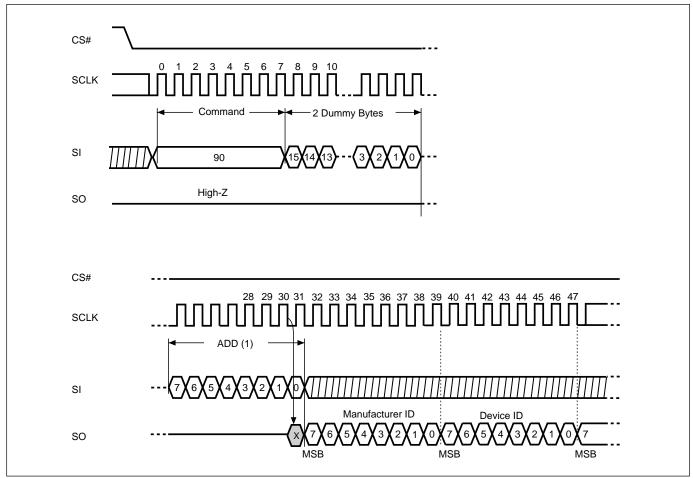










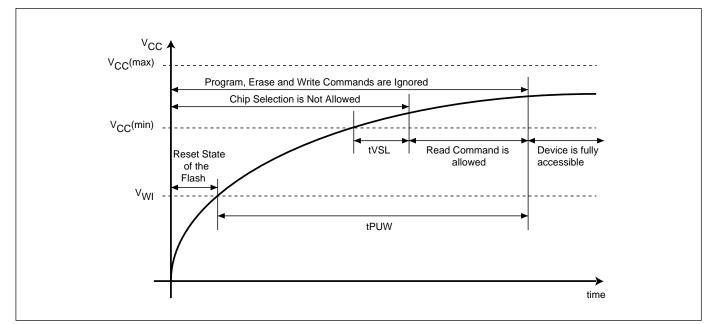


Notes:

(1) ADD=00H will output the manufacturer's ID first and ADD=01H will output device ID first(2) Instruction is either 90(hex) or EF(hex).



Figure 29. Power-up Timing



Note: VCC (max.) is 3.6V and VCC (min.) is 2.7V.



RECOMMENDED OPERATING CONDITIONS

At Device Power-Up

AC timing illustrated in Figure A is recommended for the supply voltages and the control signals at device power-up. If the timing in the figure is ignored, the device may not operate correctly.

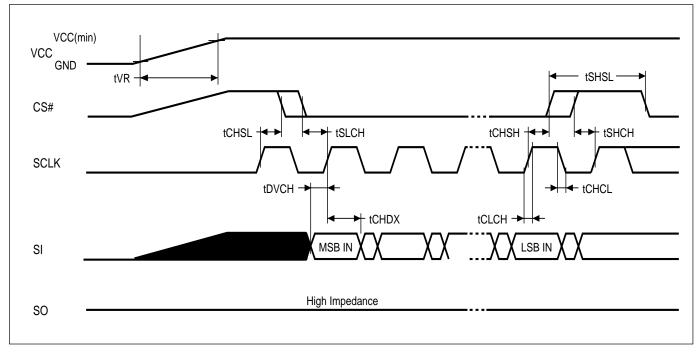


Figure A. AC Timing at Device Power-Up

| Symbol | Parameter | Notes | Min. | Max. | Unit |
|--------|---------------|-------|------|--------|------|
| tVR | VCC Rise Time | 1 | 20 | 500000 | us/V |

Notes :

1. Sampled, not 100% tested.

2. For AC spec tCHSL, tSLCH, tDVCH, tCHDX, tSHSL, tCHSH, tSHCH, tCHCL, tCLCH in the figure, please refer to "AC CHARACTERISTICS" table.



ERASE AND PROGRAMMING PERFORMANCE

| PARAMETER | | Min. | TYP. (1) | Max. (2) | UNIT |
|--|---------|------|----------|----------|--------|
| Write Status Register Cycle Time | | | 40 | 100 | ms |
| Sector Erase Time | | | 90 | 300 | ms |
| Block Erase Time | | | 0.7 | 2 | S |
| | 64Mb | | 50 | 80 | S |
| Chip Erase Time | 32Mb | | 25 | 50 | S |
| | 16Mb | | 14 | 30 | S |
| | 64Mb | | 30 | 48 | S |
| Chip Erase Time (at ACC mode) | 32Mb | | 15 | 30 | S |
| | 16Mb | | 8 | 18 | S |
| Byte Program Time (via page program co | ommand) | | 9 | 300 | us |
| Page Program Time | | | 1.4 | 5 | ms |
| Page Program Time (at ACC mode) | | | 1.4 | 5 | ms |
| Erase/Program Cycle | | | 100,000 | | cycles |

Note:

- 1. Typical program and erase time assumes the following conditions: 25°C, 3.3V, and checker board pattern.
- 2. Under worst conditions of 85°C and 2.7V.
- 3. System-level overhead is the time required to execute the first-bus-cycle sequence for the programming command.
- 4. Erase/Program cycles comply with JEDEC JESD-47E & A117A standard

LATCH-UP CHARACTERISTICS

| | MIN. | MAX. |
|---|--------|------------|
| Input Voltage with respect to GND on ACC | -1.0V | 11.5V |
| Input Voltage with respect to GND on all power pins, SI, CS# | -1.0V | 2 VCCmax |
| Input Voltage with respect to GND on SO | -1.0V | VCC + 1.0V |
| Current | -100mA | +100mA |
| Includes all pins except VCC. Test conditions: VCC = 3.0V, one pin at a til | me. | |

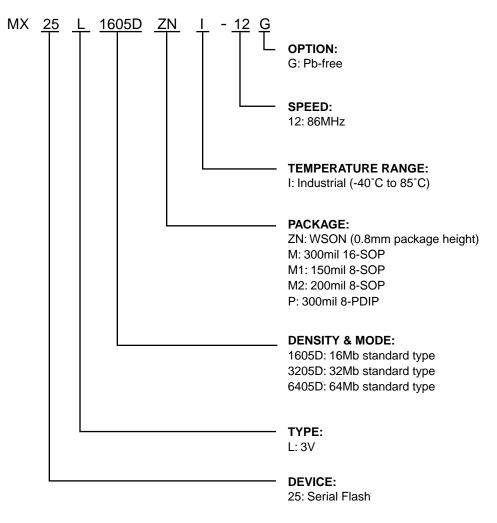


ORDERING INFORMATION

| PART NO. | CLOCK (MHz) | OPERATING CURRENT MAX. (mA) | STANDBY CURRENT MAX (uA) | Temperature | PACKAGE | Remark |
|-------------------|----------------|-----------------------------------|--------------------------------|-------------|--------------------|---------|
| MX25L1605DM2I-12G | 86 | 25 | 20 | -40°C~85°C | 8-SOP (200mil) | Pb-free |
| MX25L1605DMI-12G | 86 | 25 | 20 | -40°C~85°C | 16-SOP | Pb-free |
| MX25L1605DM1I-12G | 86 | 25 | 20 | -40°C~85°C | 8-SOP (150mil) | Pb-free |
| MX25L1605DPI-12G | 86 | 25 | 20 | -40°C~85°C | 8-PDIP (300mil) | Pb-free |
| MX25L1605DZNI-12G | 86 | 25 | 20 | -40°C~85°C | 8-WSON (6x5mm) | Pb-free |
| MX25L3205DZNI-12G | 86 | 25 | 20 | -40°C~85°C | 8-WSON (6x5mm) | Pb-free |
| MX25L3205DM2I-12G | 86 | 25 | 20 | -40°C~85°C | 8-SOP (200mil) | Pb-free |
| MX25L3205DMI-12G | 86 | 25 | 20 | -40°C~85°C | 16-SOP | Pb-free |
| MX25L3205DPI-12G | 86 | 25 | 20 | -40°C~85°C | 8-PDIP (300mil) | Pb-free |
| MX25L6405DZNI-12G | 86 | 25 | 20 | -40°C~85°C | 8-WSON (8x6mm) | Pb-free |
| MX25L6405DMI-12G | 86 | 25 | 20 | -40°C~85°C | 16-SOP | Pb-free |



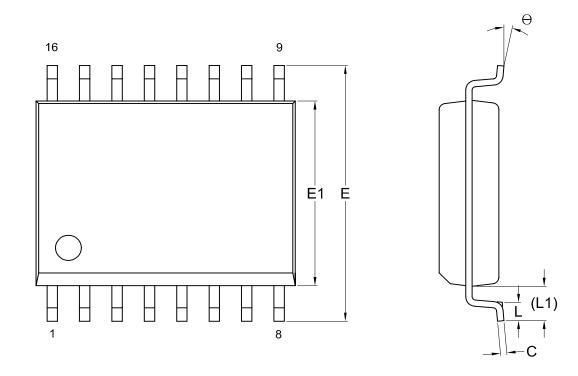
PART NAME DESCRIPTION

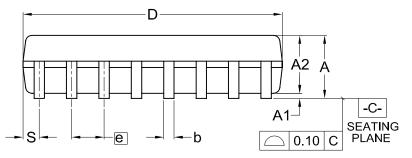




PACKAGE INFORMATION

Title: Package Outline for SOP 16L (300MIL)



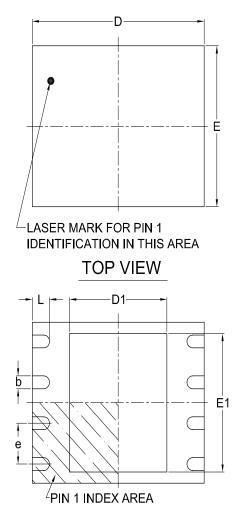


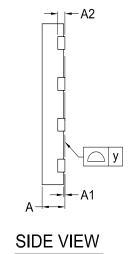
| SY UNIT | | Α | A1 | A2 | b | С | D | Е | E1 | е | L | L1 | S | θ |
|------------|------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|---------------|---|
| | Min. | | 0.10 | 2.25 | 0.36 | 0.20 | 10.10 | 10.10 | 7.42 | | 0.40 | 1.31 | 0.51 | 0 |
| mm | Nom. | - | 0.20 | 2.31 | 0.41 | 0.25 | 10.30 | 10.30 | 7.52 | 1.27 | 0.84 | 1.44 | 0.64 | 5 |
| | Max. | 2.65 | 0.30 | 2.40 | 0.51 | 0.30 | 10.50 | 10.50 | 7.60 | | 1.27 | 1.57 | 0 <u>.</u> 77 | 8 |
| | Min. | | 0.004 | 0.089 | 0.014 | 0.008 | 0.397 | 0.397 | 0.292 | | 0.016 | 0.052 | 0.020 | 0 |
| Inch | Nom. | | 0.008 | 0.091 | 0.016 | 0.010 | 0.405 | 0.405 | 0.296 | 0.050 | 0.033 | 0.057 | 0.025 | 5 |
| | Max. | 0.104 | 0.012 | 0.094 | 0.020 | 0.012 | 0.413 | 0.413 | 0.299 | | 0.050 | 0.062 | 0.030 | 8 |

| | REVISION | | | | |
|-----------|----------|--------|------|--|------------|
| DWG.NO. | REVISION | JEDEC | EIAJ | | ISSUE DATE |
| 6110-1402 | 8 | MS-013 | | | 03-07-'06 |



Title: Package Outline for WSON 8L (6x5x0.8MM, LEAD PITCH 1.27MM)



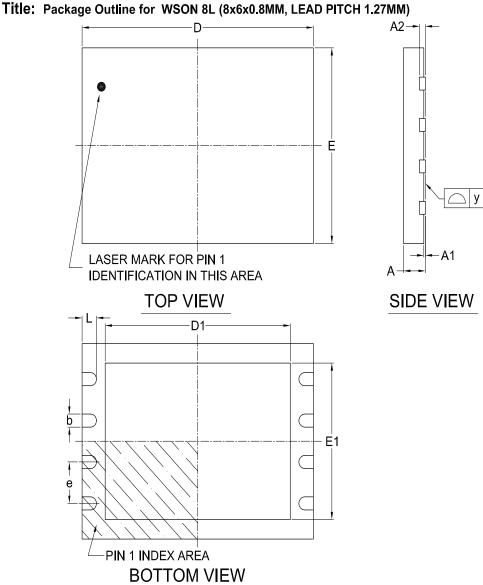


BOTTOM VIEW

- *1 : This package has exposed metal pad underneath the package, it can't contact to metal trace or pad on board.
- *2 : The exposed pad size must not violate the min. metal separtion requirement, 0.2mm with terminals.

| S) UNIT | YMBOL | Α | A1 | A2 | b | D | D1 | Е | E1 | L | е | У | |
|------------|--------|-------|----------|-------|-------------------------|-------|-------|-------|-------|-------|------------|-------|--|
| | Min. | 0.70 | | | 0.35 | 5.90 | 3.30 | 4.90 | 3.90 | 0.50 | — | 0.00 | |
| mm | Nom. | _ | | 0.20 | 0.40 | 6.00 | 3.40 | 5.00 | 4.00 | 0.60 | 1.27 | — | |
| | Max. | 0.80 | 0.05 | | 0.48 | 6.10 | 3.50 | 5.10 | 4.10 | 0.75 | _ | 0.08 | |
| | Min. | 0.028 | | | 0.014 | 0.232 | 0.129 | 0.193 | 0.154 | 0.020 | _ | 0.00 | |
| Inch | Nom. | _ | | 0.008 | 0.016 | 0.236 | 0.134 | 0.197 | 0.157 | 0.024 | 0.05 | — | |
| | Max. | 0.032 | 0.002 | | 0.019 | 0.240 | 0.138 | 0.201 | 0.161 | 0.030 | _ | 0.003 | |
| DV | VG.NO | - | REVISION | | REFERENCE JEDEC EIAJ | | | | | | ISSUE DATE | | |
| 611 | 0-3401 | | 4 | | MO-220 | | | | | | 2007/0 | 9/20 | |





Dimensions (inch dimensions are derived from the original mm dimensions)

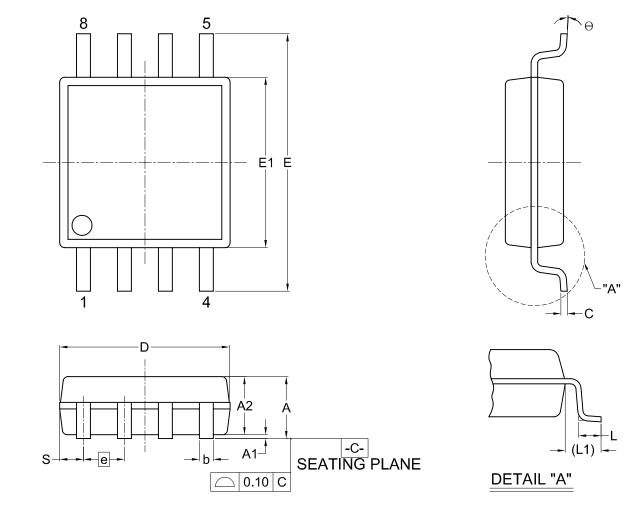
*1 : This package has exposed metal pad underneath the package, it can't contact to metal trace or pad on board.

*2 : The exposed pad size must not violate the min. metal separtion requirement, 0.2mm with terminals.

| SY UNIT | (MBOL | Α | A1 | A2 | b | D | D1 | E | E1 | L | e | у |
|----------------|-----------------------------|-------|-------|--------|-------|-------|-------|-------|------------|--------|------|-------|
| | Min. | 0.70 | | — | 0.35 | 7.90 | 4.65 | 5.90 | 4.55 | 0.40 | — | 0.00 |
| mm | Nom. | | | 0.20 | 0.40 | 8.00 | 4.70 | 6.00 | 4.60 | 0.50 | 1.27 | _ |
| | Max. | 0.80 | 0.05 | — | 0.48 | 8.10 | 4.75 | 6.10 | 4.65 | 0.60 | | 0.08 |
| | Min. | 0.028 | | _ | 0.014 | 0.311 | 0.183 | 0.232 | 0.179 | 0.016 | — | 0.00 |
| Inch | Nom. | | | 0.008 | 0.016 | 0.315 | 0.185 | 0.236 | 0.181 | 0.020 | 0.05 | _ |
| | Max. | 0.032 | 0.002 | — | 0.019 | 0.319 | 0.187 | 0.240 | 0.183 | 0.024 | — | 0.003 |
| DW | DWG.NO. REVISION JEDEC EIAJ | | | | | | | | ISSUE DATE | | | |
| 6110-3402 4 MC | | | | MO-220 | | | | | | 2007/1 | 0/02 | |





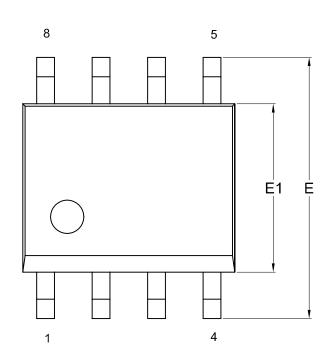


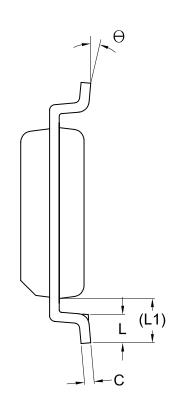
| SY UNIT | | Α | A 1 | A2 | b | С | D | Е | E1 | е | L | L1 | S | θ |
|------------|------|-------|------------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|---|
| | Min. | | 0.05 | 1.70 | 0.36 | 0.19 | 5.13 | 7.70 | 5.18 | | 0.50 | 1.21 | 0.62 | 0 |
| mm | Nom. | | 0.15 | 1.80 | 0.41 | 0.20 | 5.23 | 7.90 | 5.28 | 1.27 | 0.65 | 1.31 | 0.74 | 5 |
| | Max. | 2.16 | 0.25 | 1.91 | 0.51 | 0.25 | 5.33 | 8.10 | 5.38 | | 0.80 | 1.41 | 0.88 | 8 |
| | Min. | | 0.002 | 0.067 | 0.014 | 0.007 | 0.202 | 0.303 | 0.204 | | 0.020 | 0.048 | 0.024 | 0 |
| Inch | Nom. | | 0.006 | 0.071 | 0.016 | 0.008 | 0.206 | 0.311 | 0.208 | 0.050 | 0.026 | 0.052 | 0.029 | 5 |
| | Max. | 0.009 | 0.010 | 0.075 | 0.020 | 0.010 | 0.210 | 0.319 | 0.212 | | 0.031 | 0.056 | 0.035 | 8 |

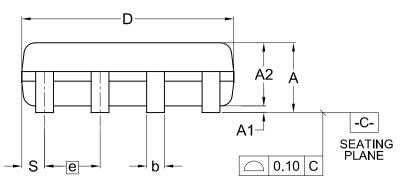
| | DWG.NO. REVISION | | REFERENCE | | | | | |
|-----------|------------------|-------|-----------|--|------------|--|--|--|
| DWG.NO. | REVISION | JEDEC | EIAJ | | ISSUE DATE | | | |
| 6110-1406 | 1 | | | | 05-06-'05 | | | |



Title: Package Outline for SOP 8L (150MIL)





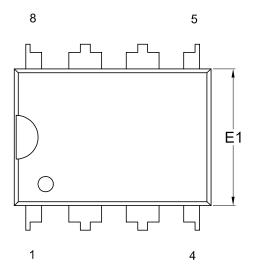


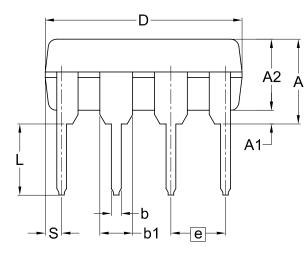
| SY UNIT | | А | A1 | A2 | b | С | D | Е | E1 | е | L | L1 | S | θ |
|------------|------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|---|
| | MIn. | | 0.10 | 1.35 | 0.36 | 0.15 | 4.77 | 5.80 | 3.80 | | 0.46 | 0.85 | 0.41 | 0 |
| mm | Nom. | | 0.15 | 1.45 | 0.41 | 0.20 | 4.90 | 5.99 | 3.90 | 1.27 | 0.66 | 1.05 | 0.54 | 5 |
| | Max. | 1.75 | 0.20 | 1.55 | 0.51 | 0.25 | 5.03 | 6.20 | 4.00 | | 0.86 | 1.25 | 0.67 | 8 |
| | Min. | | 0.004 | 0.053 | 0.014 | 0.006 | 0.188 | 0.228 | 0.150 | | 0.018 | 0.033 | 0.016 | 0 |
| Inch | Nom. | | 0.006 | 0.057 | 0.016 | 0.008 | 0.193 | 0.236 | 0.154 | 0.050 | 0.026 | 0.041 | 0.021 | 5 |
| | Max. | 0.069 | 0.008 | 0.061 | 0.020 | 0.010 | 0.198 | 0.244 | 0.158 | | 0.034 | 0.049 | 0.026 | 8 |

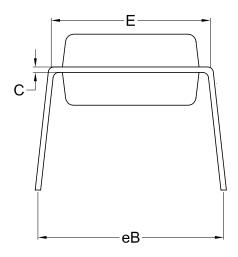
| DWG.NO. | REVISION | | ISSUE DATE | | |
|-----------|----------|------------|------------|--|------------|
| DWG.NO. | REVISION | JEDEC EIAJ | | | ISSUE DATE |
| 6110-1401 | 6 | MS-012 | | | 11-26-'03 |



Title: Package Outline for PDIP 8L (300MIL)







| SY UNIT | 'MBOL | А | A1 | A2 | b | b1 | С | D | Е | E1 | e | eВ | L | S |
|------------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|
| mm | Min. | ļ | 0.38 | 3.18 | 0.36 | 1.14 | 0.20 | 9.02 | 7.62 | 6.22 | - | 7.87 | 2.92 | 0.76 |
| | Nom. | | - | 3.30 | 0.46 | 1.52 | 0.25 | 9.27 | 7.87 | 6.35 | 2.54 | 8.89 | 3.30 | 1.14 |
| | Max. | 5.33 | | 3.43 | 0.56 | 1.78 | 0.36 | 10.16 | 8.13 | 6.48 | | 9.53 | 3.81 | 1.52 |
| | Min. | | 0.015 | 0.125 | 0.014 | 0.045 | 0.008 | 0.355 | 0.300 | 0.245 | _ | 0.310 | 0.115 | 0.030 |
| Inch | Nom. | | | 0.130 | 0.018 | 0.060 | 0.010 | 0.365 | 0.310 | 0.250 | 0.100 | 0.350 | 0.130 | 0.045 |
| | Max. | 0.210 | - | 0.135 | 0.022 | 0.070 | 0.014 | 0.400 | 0.320 | 0.255 | _ | 0.375 | 0.150 | 0.060 |

| | REVISION | | ISSUE DATE | | |
|-----------|----------|--------|------------|--|------------|
| DWG.NO. | REVISION | JEDEC | EIAJ | | 1550E DATE |
| 6110-0201 | 6 | MS-001 | | | 09-01-'06 |



REVISION HISTORY

| Revision No. | Description | Page | Date |
|---------------------|--------------------------|------------|-------------|
| 1.0 | 1. Removed "Preliminary" | P1 | MAR/07/2008 |
| 1.1 | 1. Dual I/O Pre-released | P1,3,21,31 | MAY/12/2008 |



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